

Angle-resolved photoemission spectroscopy: introduction and applications

Los Alamos Computational Condensed Matter Summer School 2025

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EPI Grant #12957

Outline

- Overview and experimental matters
 - Lightsources
 - Surface sensitivity
 - XPS
 - Accessing different parts of momentum space
 - Matrix elements
 - Resolution
- Applications/examples
 - Interactions and lifetimes
 - Gaps
 - Twists on ARPES technique
 - Throughout talk: examples from heavy fermions, cuprates, Weyl semimetals, topological insulators, unconventional superconductors

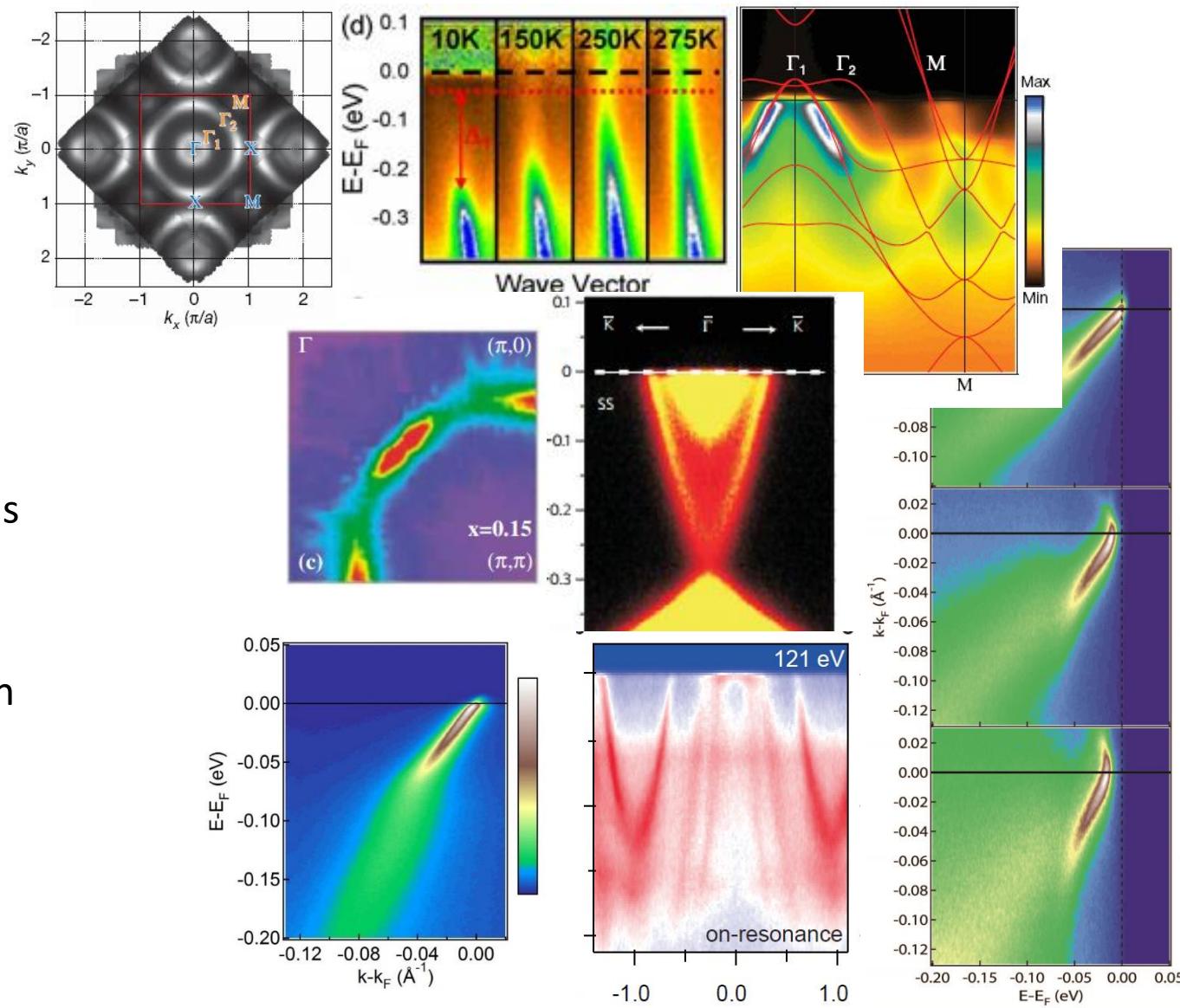
Structures in momentum space

All crystalline materials

- Brillouin zones
- Fermi surfaces
- Band dispersion

Some crystalline materials

- Charge density wave gaps
- Superconducting gaps
- Spin density wave gaps
- Magnetism that shifts bands or opens gaps
- Spin orbit coupling
- Electron-boson coupling
- Heavy fermion hybridization gaps
- Spin momentum locking
- Dirac dispersions
- Surface states
- ...



Angle-Resolved Photoemission spectroscopy overview

- Purpose: measure electronic band structure and interactions
- Photoelectric effect, conservation laws

$$E_{kin} = h\nu - \phi - |E_B|$$

$$\mathbf{p}_{\parallel} = \hbar\mathbf{k}_{\parallel} = \sqrt{2mE_{kin}} \cdot \sin \vartheta$$

Definitions:

E_{kin} = kinetic energy of photoelectron measure

$h\nu$ = photon energy Know

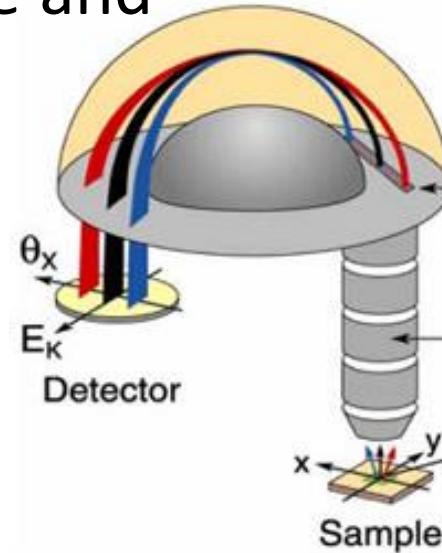
ϕ = work function know/measure (~ 4 eV)

E_B = electron binding energy inside material, relative to Fermi level want

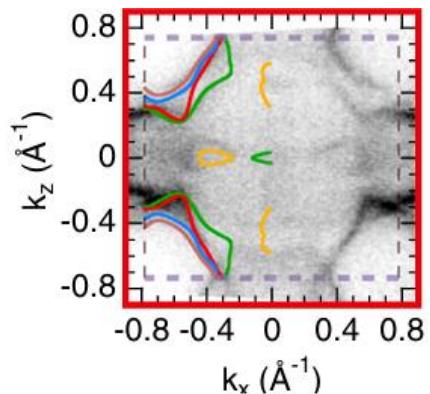
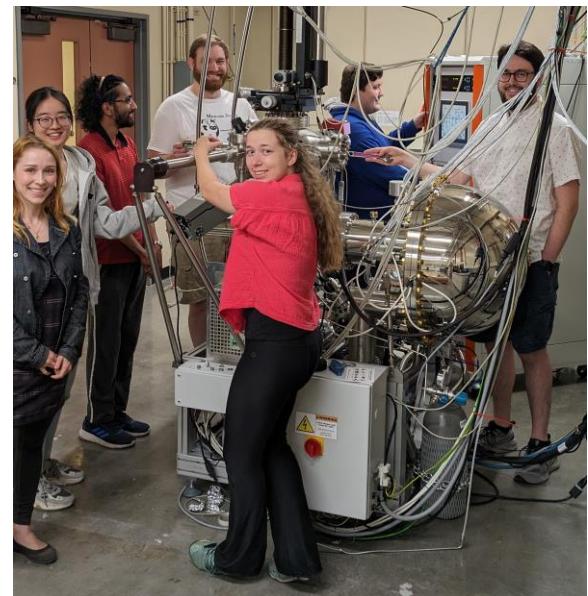
k_{\parallel} = crystal momentum, parallel to sample surface plane want

m = mass of free electron know

ϑ = emission angle of photoelectron measure

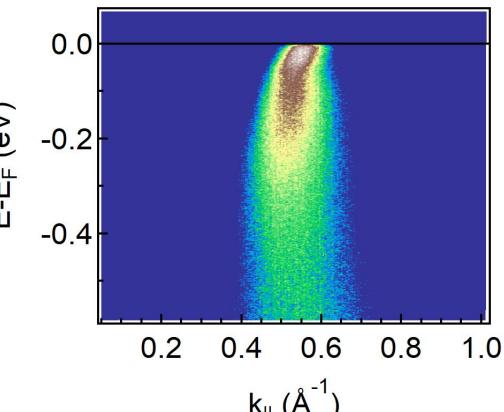


ARPES, photoemission, and ultrafast optics at UC Davis

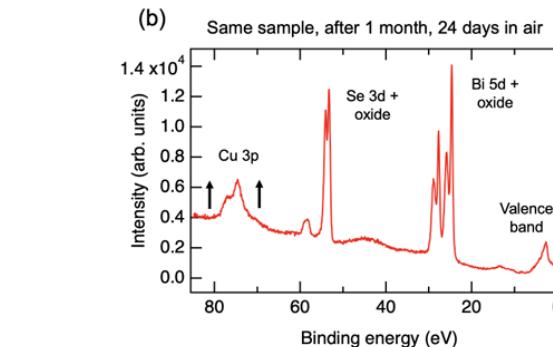


J. Badger, Y. Quan, M. C. Staab, et al, Communications Physics 5 (2022)
Staab et al, Phys. Rev. B 110, 165115 (2024)
(topo superconductor LaNiGa_2)

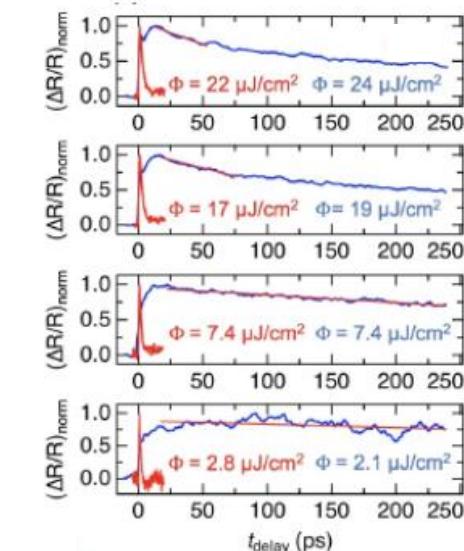
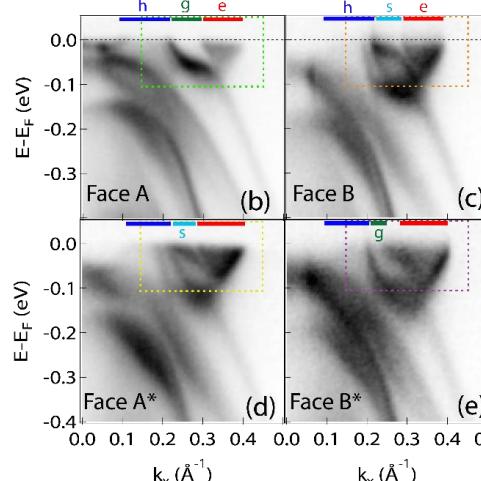
S. Sreedhar et al.
Phys. Rev. B 102,
205109 (2020)
(cuprate Hg1201)



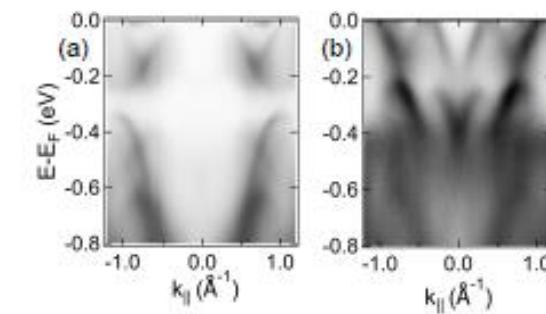
A. Rossi, et al., Phys. Rev. B 102
(2020) (2D material WTe_2)



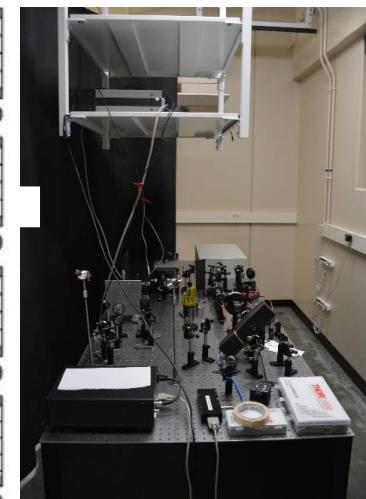
Gross et al J. Phys.
Mater. 5 044005 (2022)
(Topo SC $\text{Cu}_x\text{Bi}_2\text{Se}_3$)



A. Gross et al, Phys. Rev. B 103, L020301
(2021) ($\text{Ti Bi}_{2-x}\text{Sb}_x\text{Se}_3$)

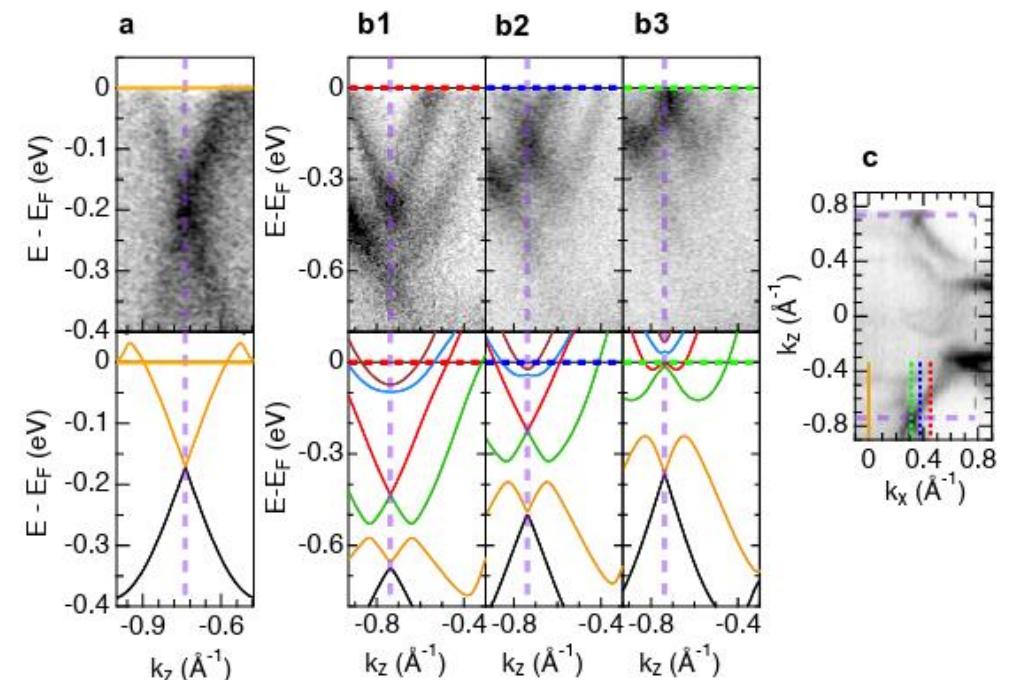
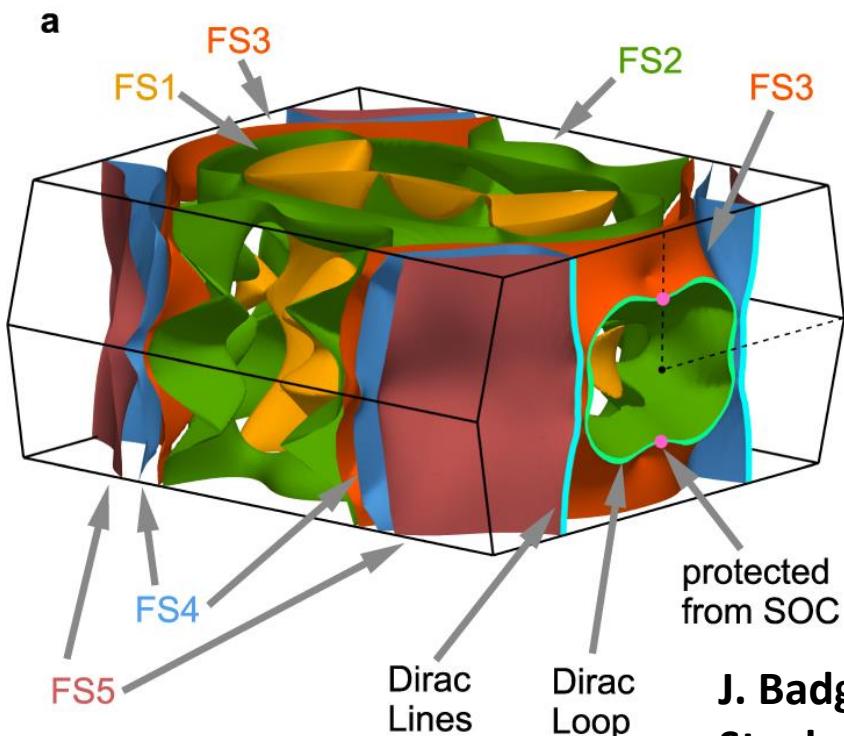


A. Rossi et al, Phys. Rev. B 104, 155115 (2021)
S. Sreedhar et al, *in preparation*
(Magnetic Weyl semimetal $\text{Co}_3\text{Sn}_2\text{S}_2$)



Meet my friend LaNiGa₂

- Possible TRSB superconductor, $T_c \sim 2\text{K}$
- 5 Fermi surfaces
- Nodal lines/loop/points on one face of the BZ enforced by non-symmorphic space group
- Near perfect match between DFT and expt



J. Badger,*et al*, Communications Physics 5 (2022)
Staab *et al*, Phys. Rev. B 110, 165115 (2024)

ARPES data: Band structure, interactions, and other things

- Interactions (electron-electron, electron-phonon, etc) can change band dispersions and quasiparticle lifetimes
- Single particle spectral function captures these interactions
- Matrix elements, resolution, and sample imperfections modify the spectrum

Single particle spectral function:

$$A(\mathbf{k}, \omega) = -\frac{1}{\pi} \frac{\Sigma''(\mathbf{k}, \omega)}{[\omega - \varepsilon_{\mathbf{k}} - \Sigma'(\mathbf{k}, \omega)]^2 + [\Sigma''(\mathbf{k}, \omega)]^2}$$

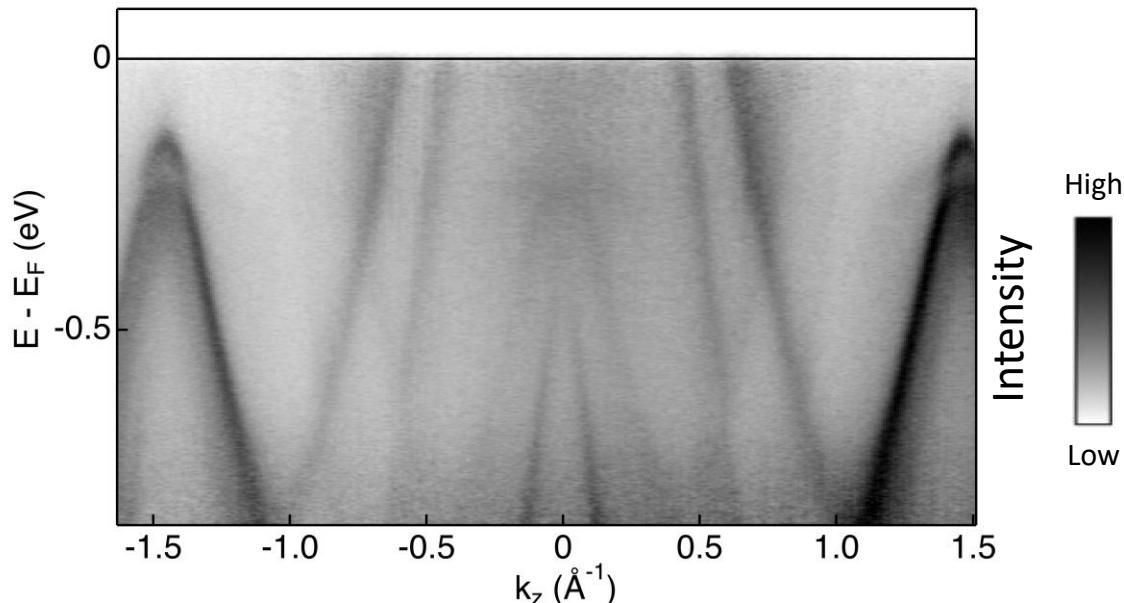
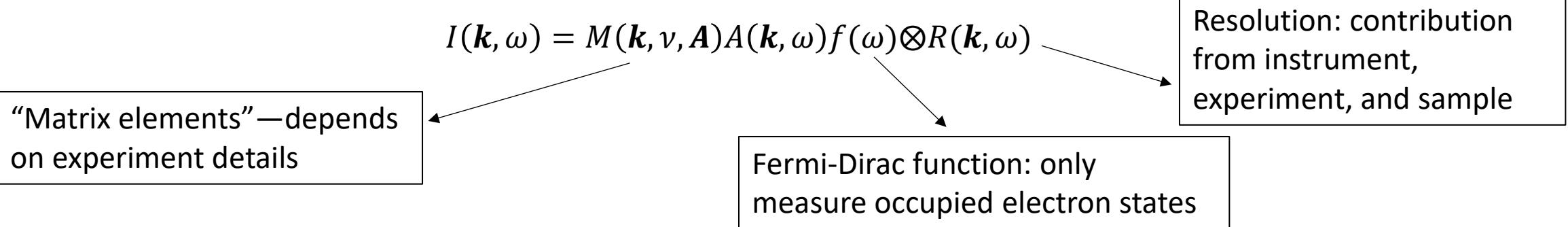
Bare band: $\varepsilon_{\mathbf{k}}$

Self Energy: $\Sigma(\mathbf{k}, \omega) = \Sigma'(\mathbf{k}, \omega) + i \Sigma''(\mathbf{k}, \omega)$

Band position

Linewidth or lifetime

Intensity in ARPES experiment



Coming slides: Discuss how experimental considerations factor into each term

Anatomy of an ARPES experiment: the lightsource

Need intense UV light for photon-hungry experiments

Laser (CW)



$h\nu$ small (<11 eV)

$h\nu$ discrete

21.2 eV (He) most common

Gas discharge lamp



Synchrotron

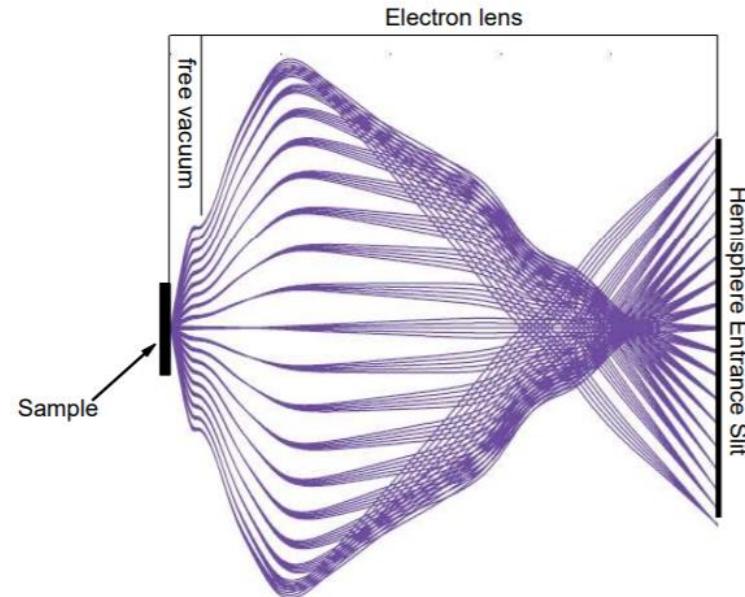


$h\nu$ variable

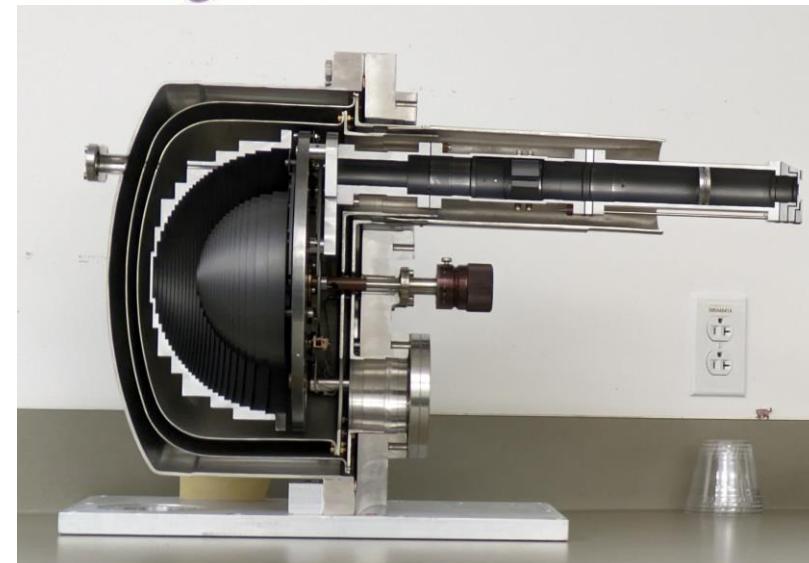
Hemispherical ARPES spectrometer/analyzer



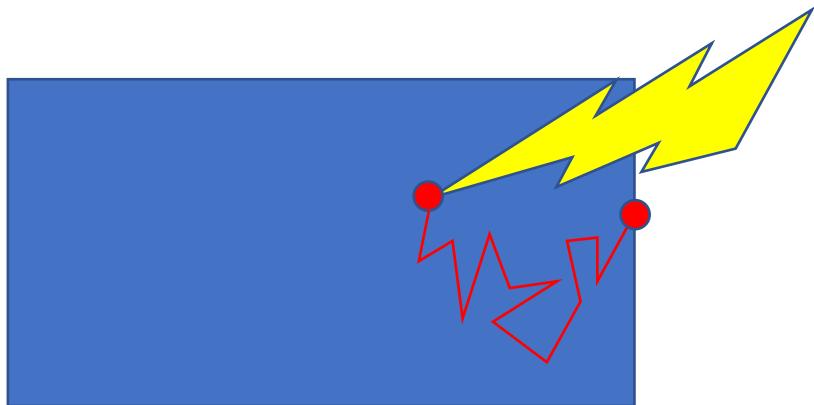
Photos from
Scienta Omicron



- Select 1D trajectory in momentum space via entrance slit
- Electrostatic lens decelerates and focuses electrons onto entrance slit
- Concentric hemispheres kept at potential difference so that electrons of different energy take different trajectory
- 2D detection of electrons, E vs k



ARPES is a surface sensitive experiment

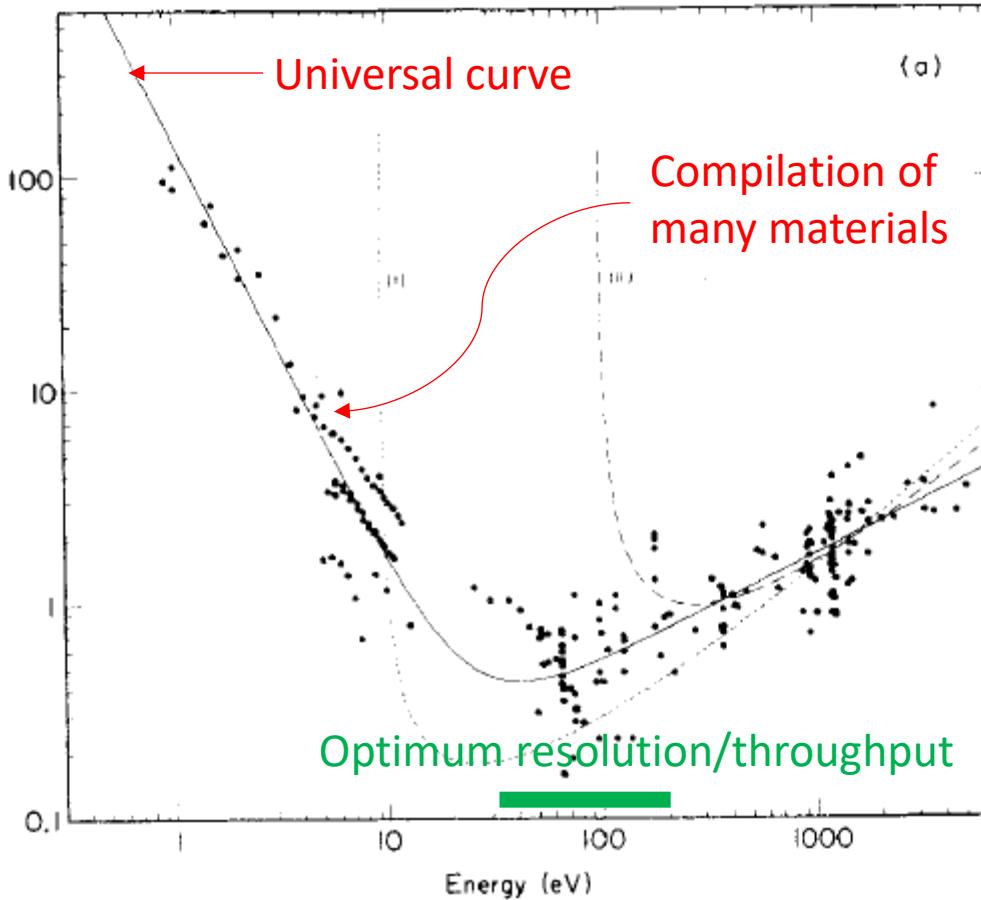


Probability of extracting electron: $\sim e^{-\frac{z}{\lambda}}$
 $z = \text{depth below surface}$
 $\lambda = \text{electrons' inelastic mean free path}$

- “information depth” $\approx 2\lambda$
- 98% of photoelectrons $\approx 4\lambda$

Empirical method for estimating λ :
S. Tanuma et al, Surf. Sci. 192, L849 (1987)

Electron inelastic mean free path, nm

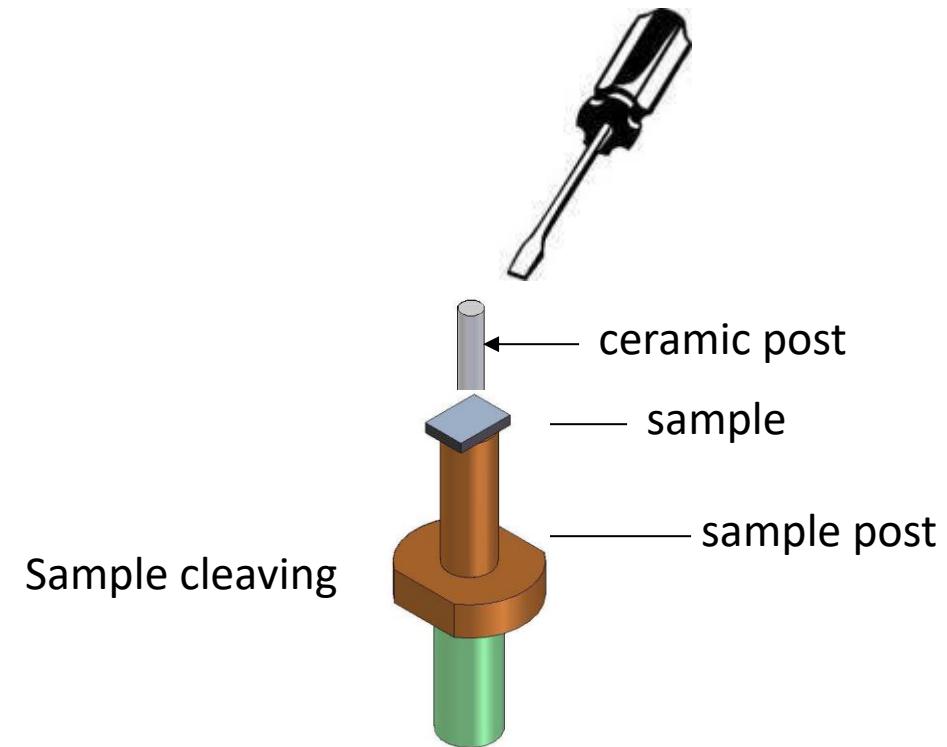


Energy=kinetic energy $\approx h\nu$ for electrons near E_F
 $E_{kin} = h\nu - \phi - |E_B|$

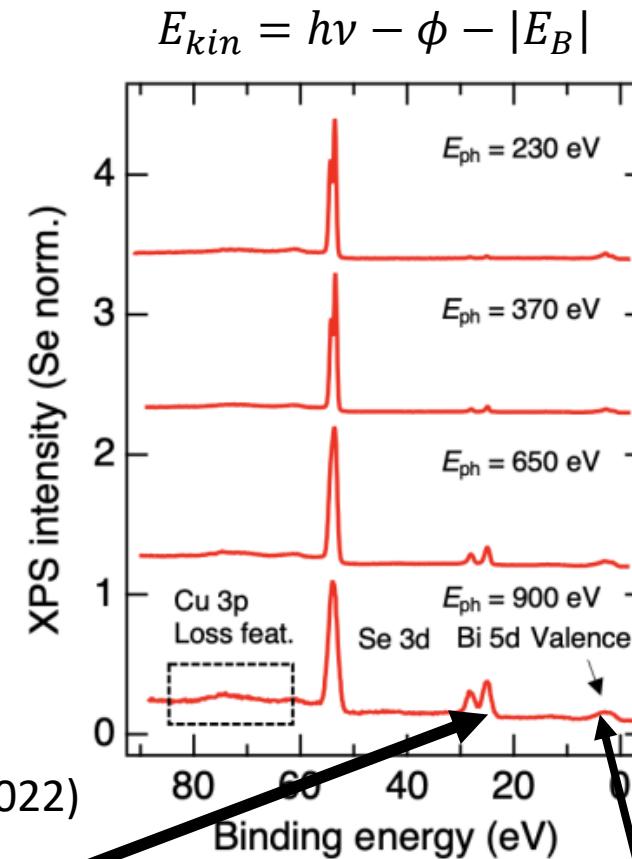
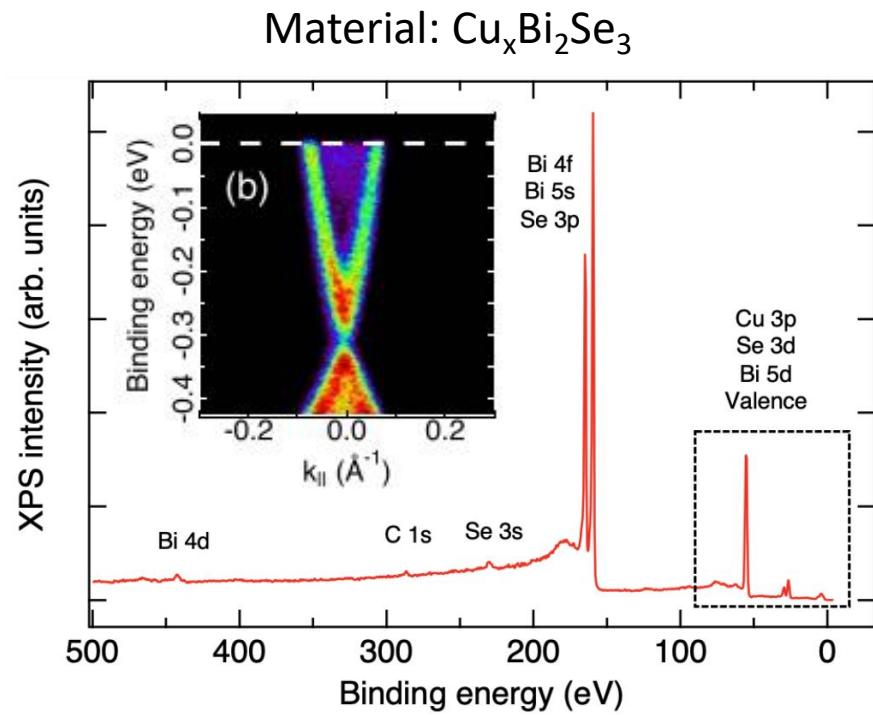
Seah and Dench,
SURFACE AND
INTERFACE ANALYSIS,
VOL. 1, NO. 1, 1979

Surface sensitivity necessitates fresh surface before each experiment

- **Cleaving in-situ**
- Growing material in-situ
- Sputter-and-anneal
- Exfoliation, if there is glove box attached to UHV
- Grow materials in external vacuum chamber and transfer via vacuum suitcase



ARPES and XPS use the same spectrometer



Adam L Gross *et al* J. Phys. Mater. **5** 044005 (2022)

“Core levels”

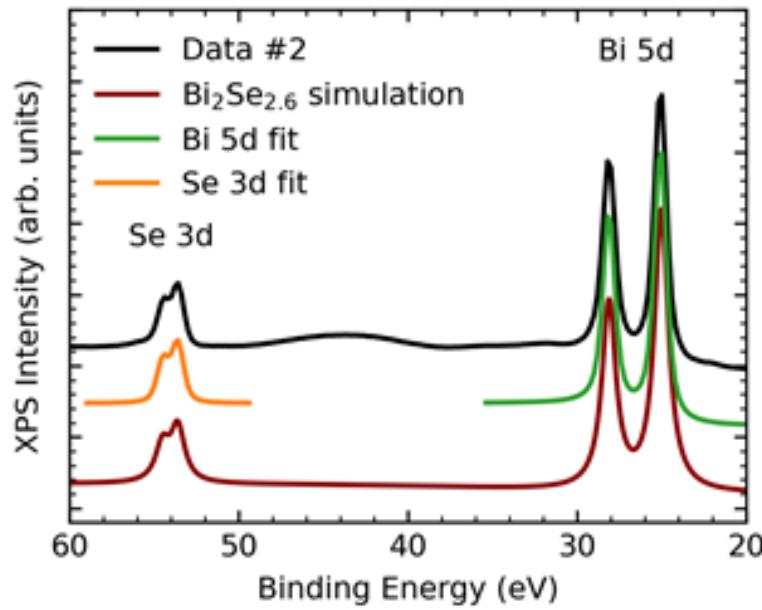
- Localized electrons → chemistry

“Valence band”

- Occupied and delocalized states
- How electrons ‘move’

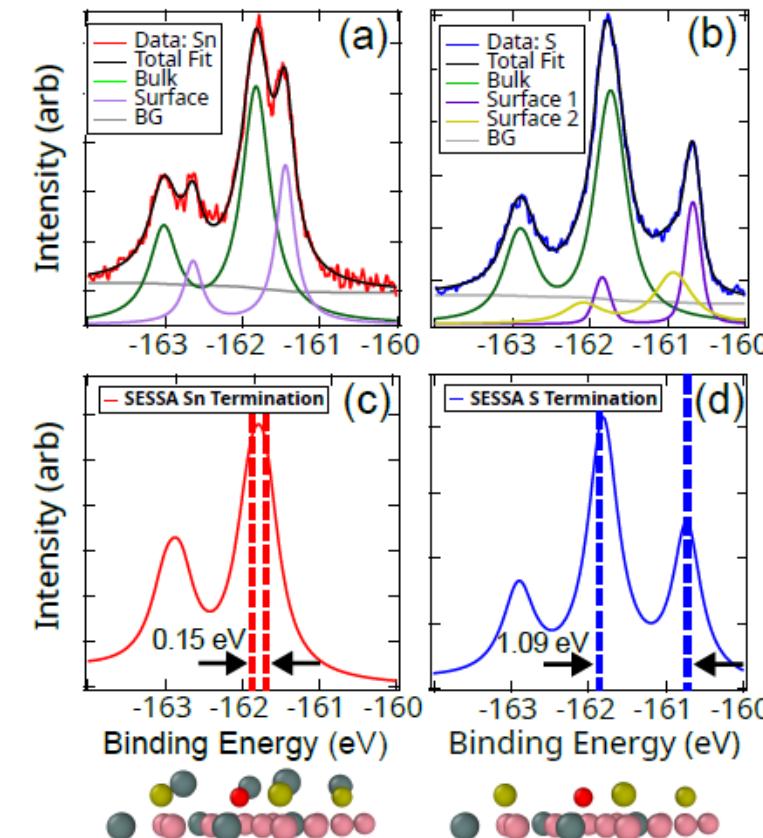
Composition of near-surface region is knowable via XPS

Example 1: Se deficiency in Bi_2Se_3 surface



Simulation: Se and Bi core level intensities weighted by photoionization cross section and depth inside sample of each chemical species

Example 2: Sn and S terminations of $\text{Co}_3\text{Sn}_2\text{S}_2$
Differing chemical shifts on different surfaces Expt + DFT



Ultrahigh vacuum (UHV) chamber ($< 10^{-10}$ torr) to maintain surface

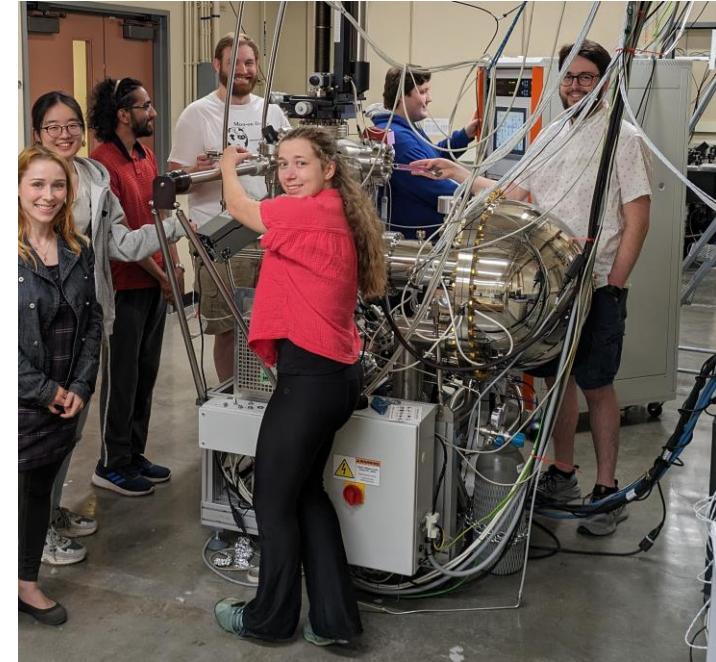
	High vacuum (HV)	Ultrahigh vacuum (UHV)
Pressure	1e-3 to 1e-9 torr	1e-9 to 1e-12 torr
Molecular mfp	10 cm to 1000km	1000 to 100,000 km
Amount of time to deposit a monolayer on sample surface*	.006s to 95 minutes	95 minutes to 65 days

$$*t = \frac{1.7 \times 10^{-6}}{0.6 * p * S}$$

p=pressure in torr

S=sticking coefficient (between 0 and 1)

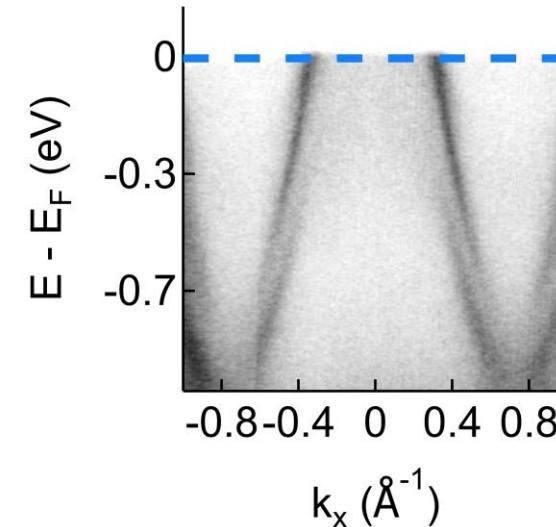
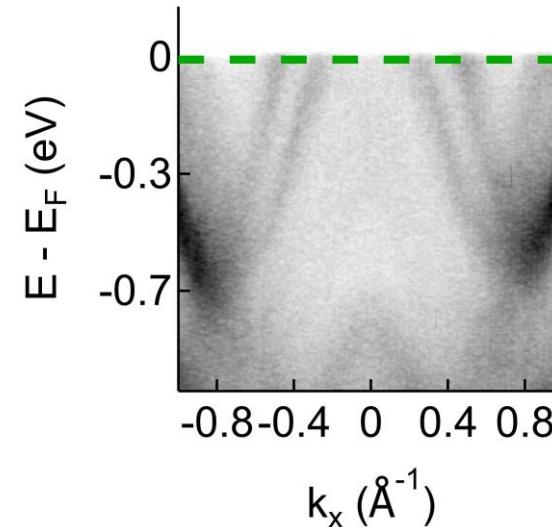
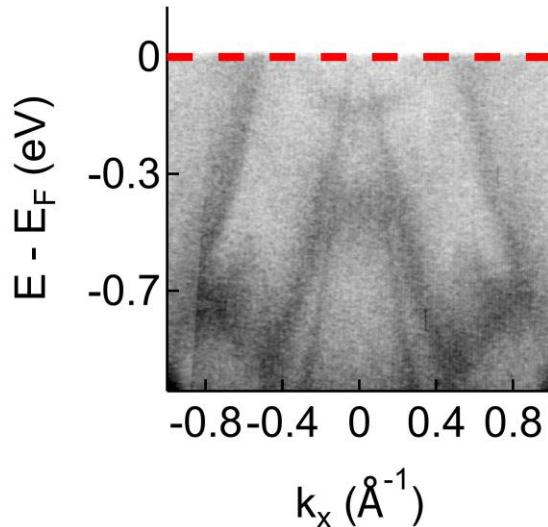
Ref: Hufner, *Photoelectron Spectroscopy*



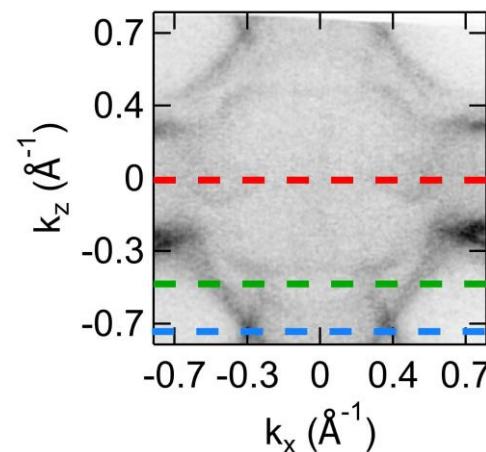
- UV light + surface adsorbates = surface chemistry
- Light elements can move and evaporate
- Fresh surfaces typically survive <48 hours in ARPES experiment

From two to three dimensional data sets

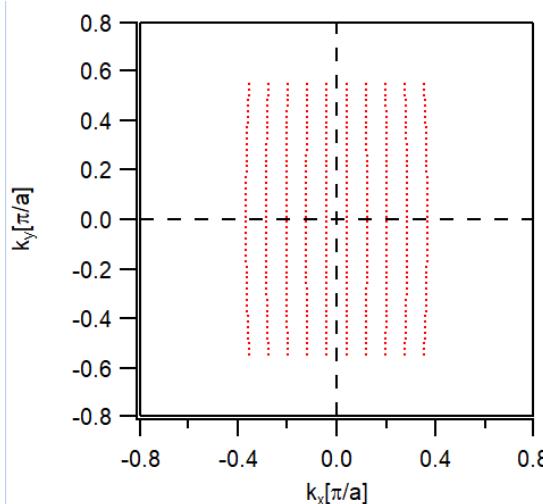
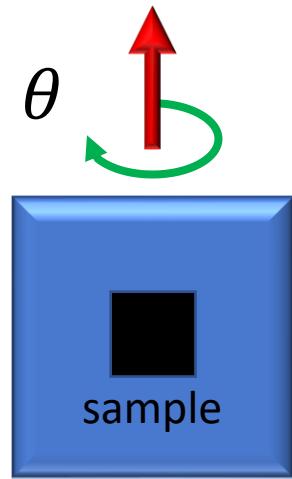
Quantum of ARPES data from hemispherical analyzer is energy vs (1D) momentum “cut”



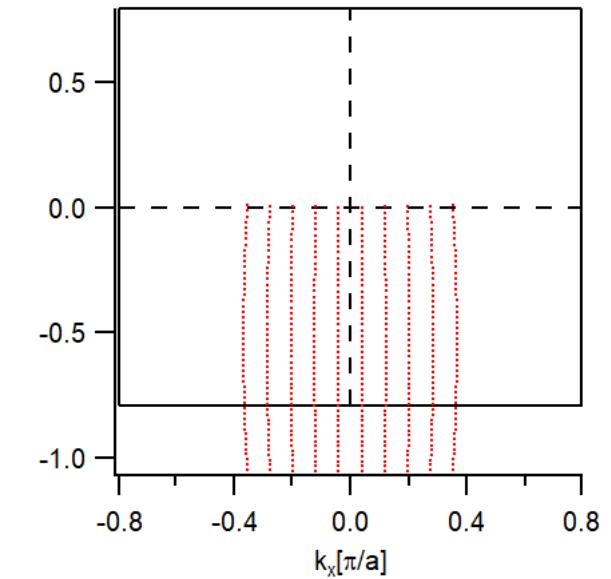
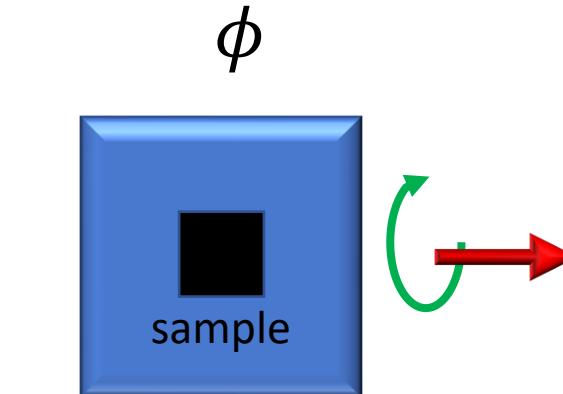
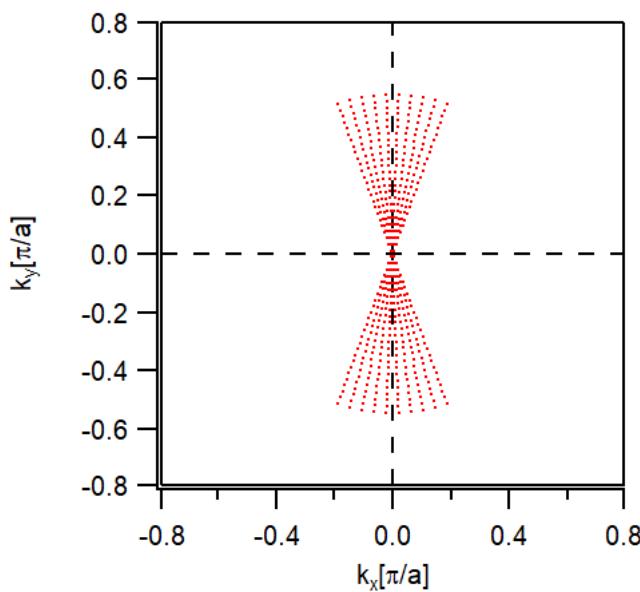
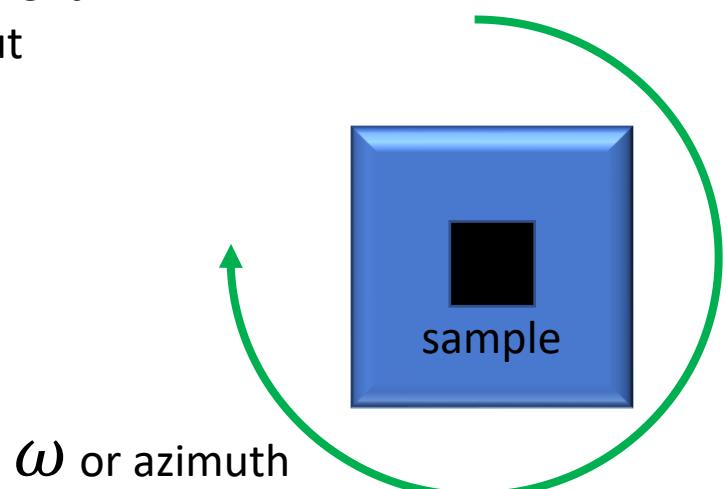
- Get energy vs 2D momentum by pasting many 1D cuts together
- This 3D data usually presented as constant-energy maps (k_x vs k_y)
- Constant-energy map at E_F is Fermi surface



Accessing different parts of the Brillouin zone (parallel momentum)

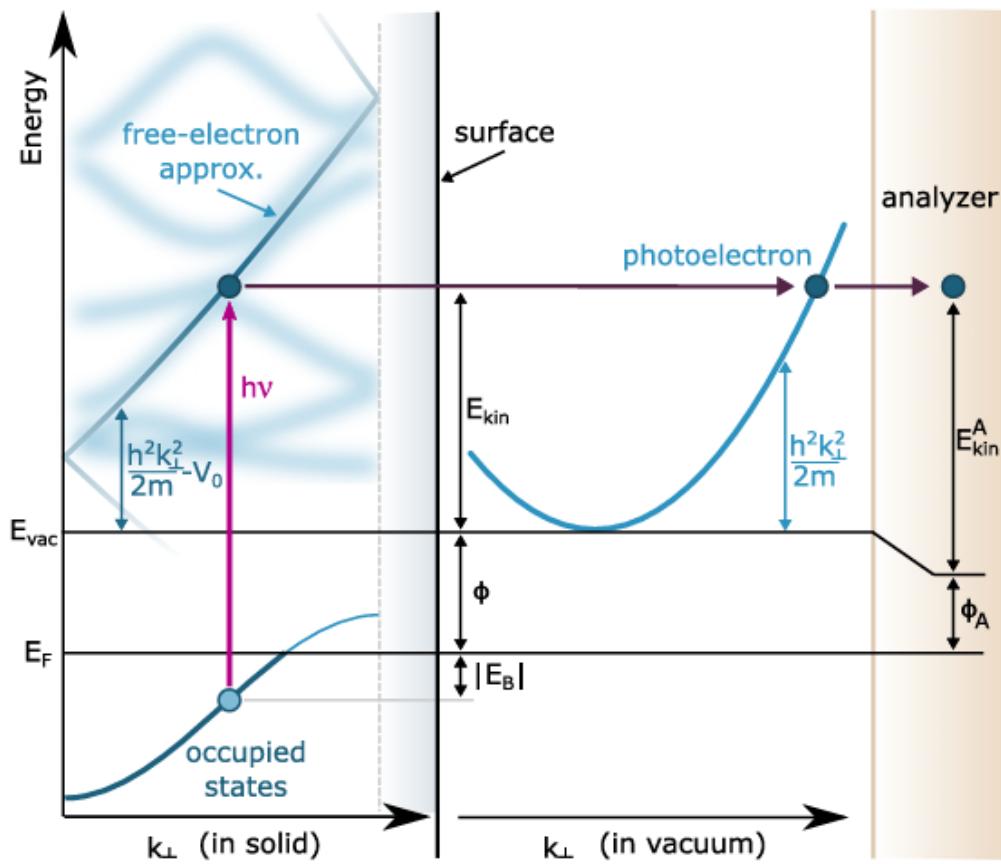


Can also do 'deflector' scan to allow equivalent of θ rotation without moving sample



$$\hbar k_{||} = \sqrt{2mE_{kin}} \sin \vartheta$$

“Final states”



Probability of electron excitation related to Fermi's golden rule:

$$w_{fi} = \frac{2\pi}{\hbar} \left| \langle \Psi_f^N | -\frac{e}{mc} \mathbf{A} \cdot \mathbf{p} | \Psi_i^N \rangle \right|^2 \delta(E_f^N - E_i^N - h\nu)$$

\mathbf{p} =electron momentum

\mathbf{A} =vector potential of photon (points in direction of polarization)

$\Psi_{i,f}^N$ =initial,final N-electron wavefunction

One-step model: photon absorption, electron excitation, and electron detection are treated as a single coherent process

Final states are usually not of direct interest, but they have implications for:

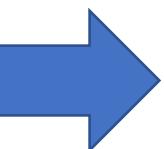
- Perpendicular momentum (assessing 3D electronic structure)
- “matrix element effects”: bands being highlighted or diminished based on experimental details

Accessing different parts of the Brillouin zone (perpendicular momentum)

$$\hbar \mathbf{k}_{\parallel} = \sqrt{2mE_{kin}} \cdot \sin \vartheta$$

In photoemission, only in plane momentum is conserved, but electrons have out-of-plane momentum too

$$E_f(\mathbf{k}) = \frac{\hbar^2 \mathbf{k}^2}{2m} - |E_0| = \frac{\hbar^2 (\mathbf{k}_{\parallel}^2 + \mathbf{k}_{\perp}^2)}{2m} - |E_0|$$



Use different photon energies to access different k_{\perp}

Final state energy

$$h\nu - |E_B|$$

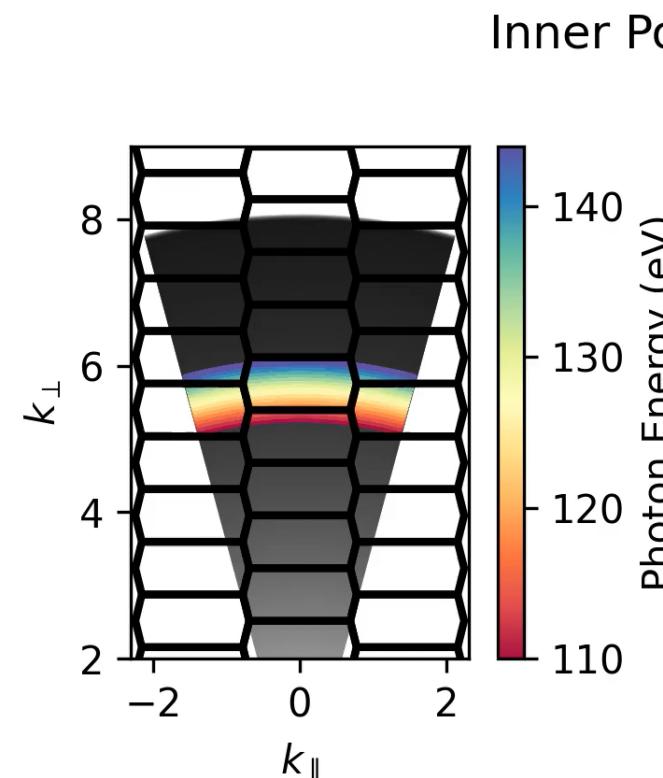
$$E_{kin} + \phi$$

~Bottom of valence band

Solve for \mathbf{k}_{\perp}

$$\mathbf{k}_{\perp} = \frac{1}{\hbar} \sqrt{2m(E_{kin} \cos^2 \vartheta + V_0)}$$

$$V_0 = |E_0| + \phi \text{ (inner potential)}$$

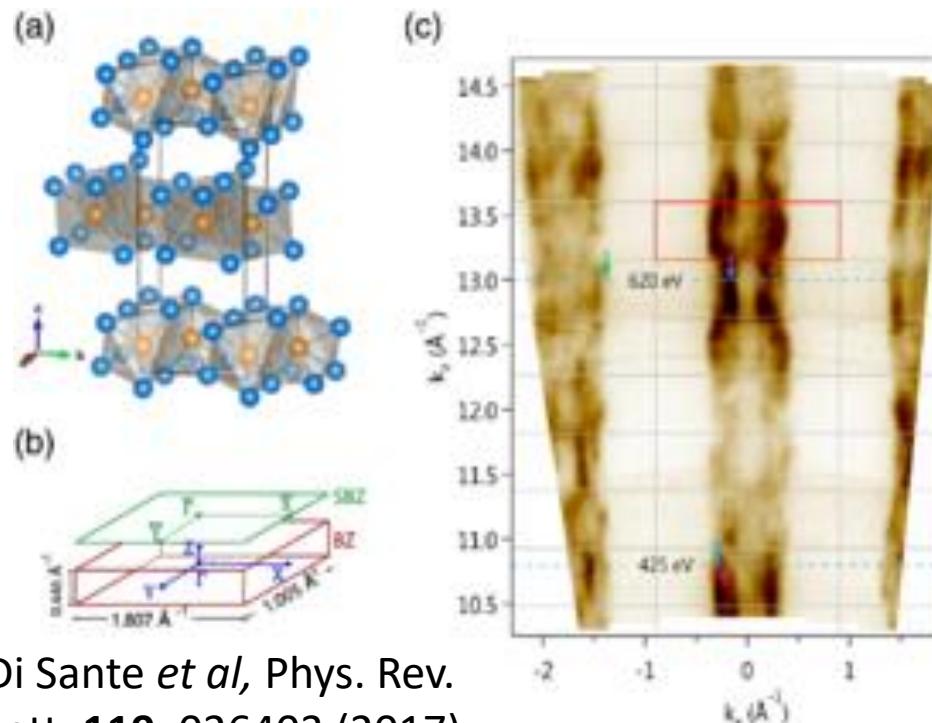


Resource for k_{\perp} : Damascelli, Physica Scripta. Vol. T109, 61–74 (2004)

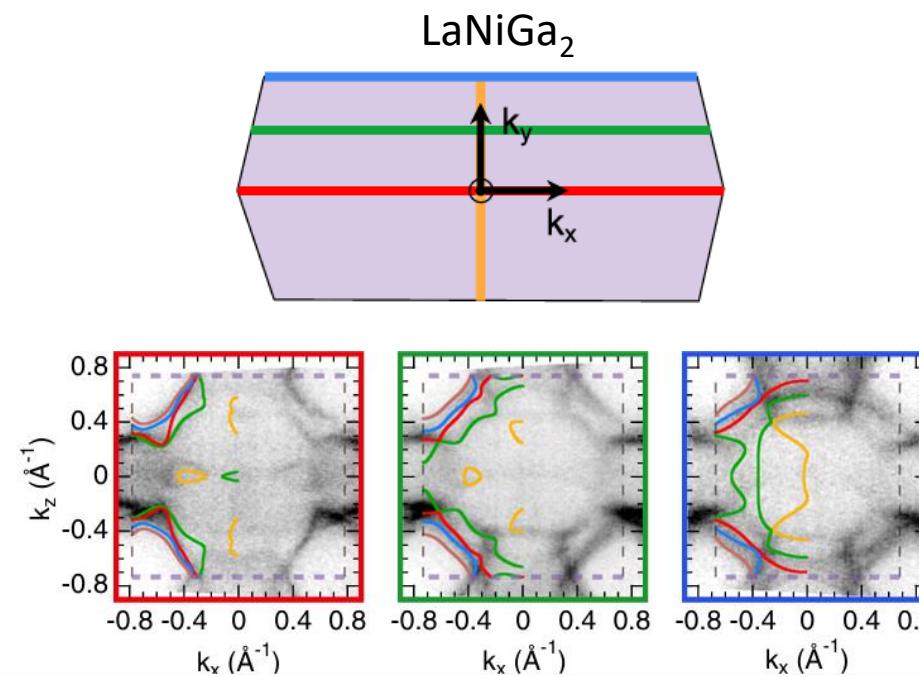
How to ascertain inner potential

Significance: Many experiments try to target specific planes of BZ (e.g. high symmetry planes, Weyl points), so connection between photon energy and BZ plane must be established

Measure multiple Brillouin zones
and find periodicity



Match to calculation

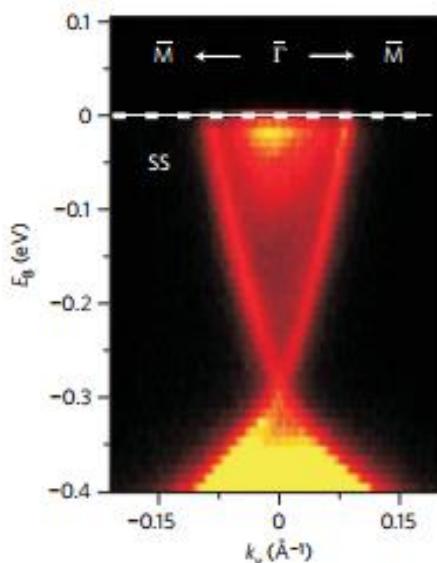


Guess a number 10-15 eV

$$V_0 = 15$$

Distinguishing surface vs bulk electronic structure

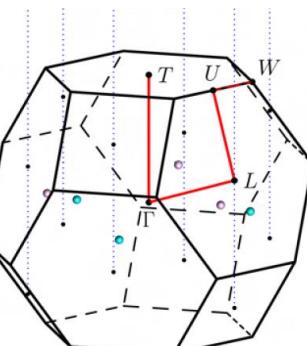
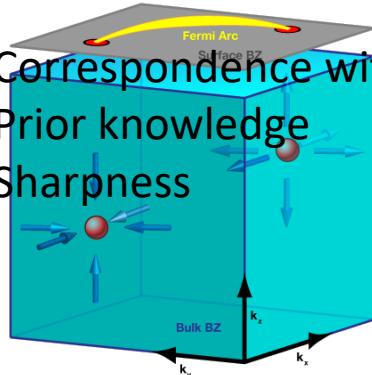
e.g. 1: Topological insulator



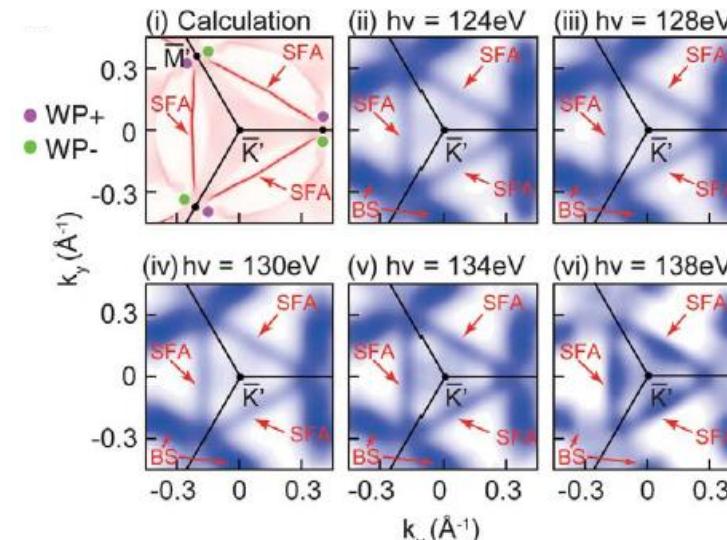
Xia et al. Nat. Phys. 5 May 2009

E.g. 2 Weyl semimetal

- Correspondence with theory
- Prior knowledge
- Sharpness

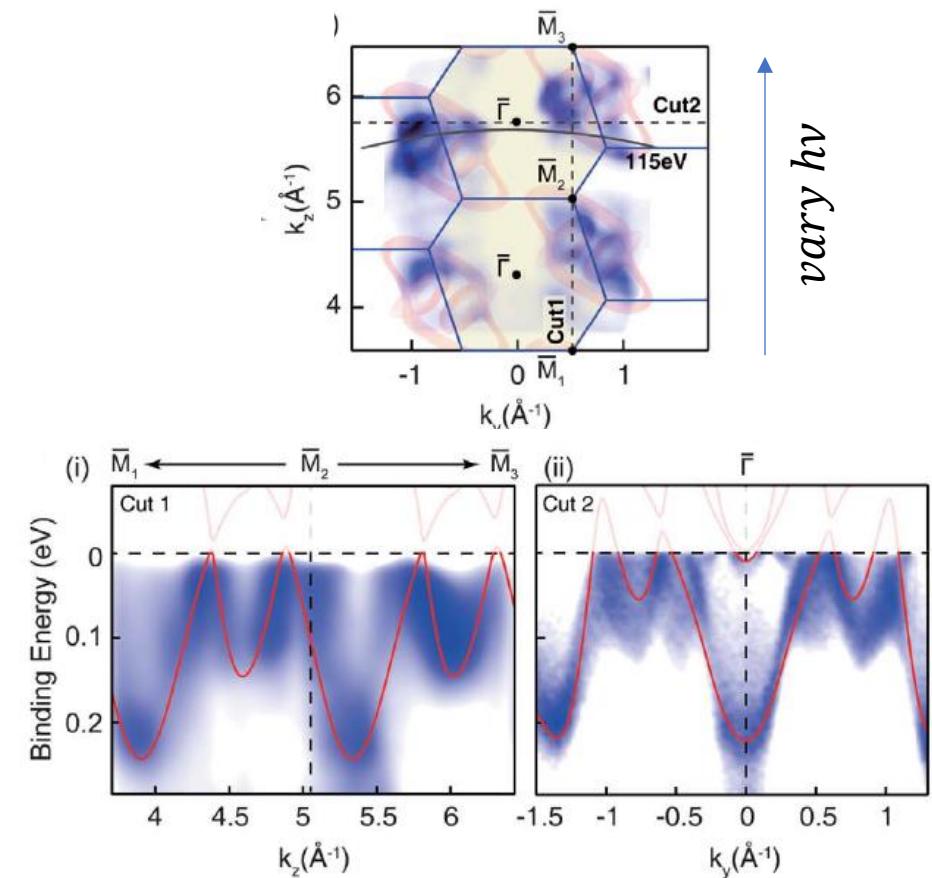


2D Surface Fermi arcs do not disperse with photon energy



$\text{Co}_3\text{Sn}_2\text{S}_2$: magnetic Weyl semimetal

3D Bulk Weyl nodes accessed by varying photon energy



Liu et al., Science 365, 1282–1285 (2019)

Matrix element effects

Express many-electron WF as antisymmetric product of 1-electron state and N-1 electron state

$$\Psi_f^N = \mathcal{A} \phi_f^k \Psi_f^{N-1}$$

$$\begin{aligned} \langle \Psi_f^N \left| -\frac{e}{mc} \mathbf{A} \cdot \mathbf{p} \right| \Psi_i^N \rangle &= \langle \phi_f^k \left| -\frac{e}{mc} \mathbf{A} \cdot \mathbf{p} \right| \phi_i^k \rangle \times \\ \Psi_m^{N-1} | \Psi_i^{N-1} \rangle &\equiv M_{f,i}^k \langle \Psi_m^{N-1} | \Psi_i^{N-1} \rangle \end{aligned}$$

$M_{f,i}^k$ = 'ARPES matrix elements'

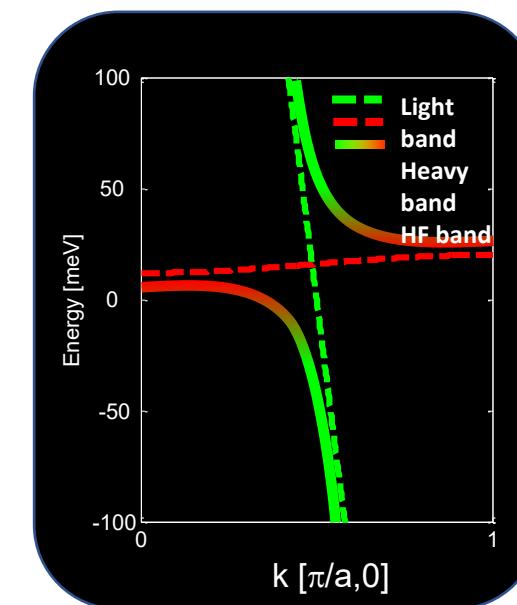
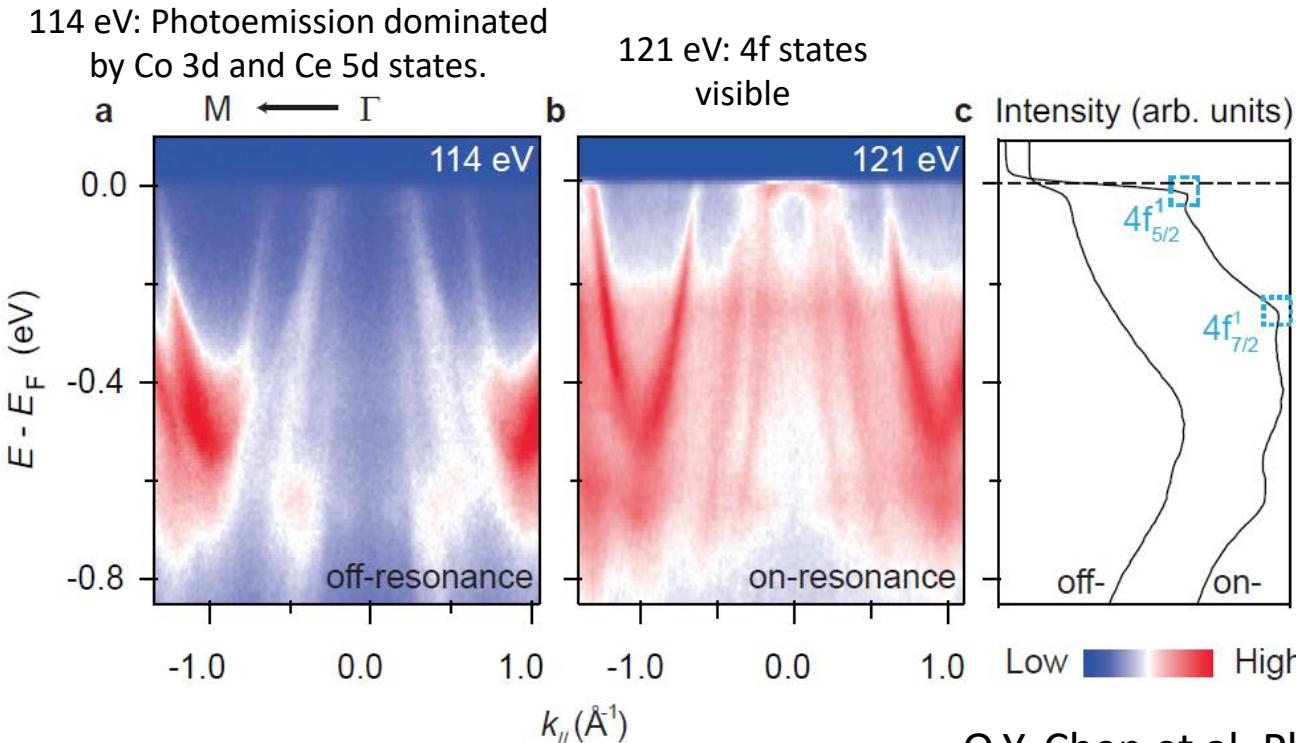
m =index given to N-1-electron **excited** state

Consequence: intensity of bands depends on their orbital character + experimental details (**photon energy, polarization, geometry**)

- Sometimes just incidental fact
- Can be exploited to highlight certain bands and/or discern their orbital character

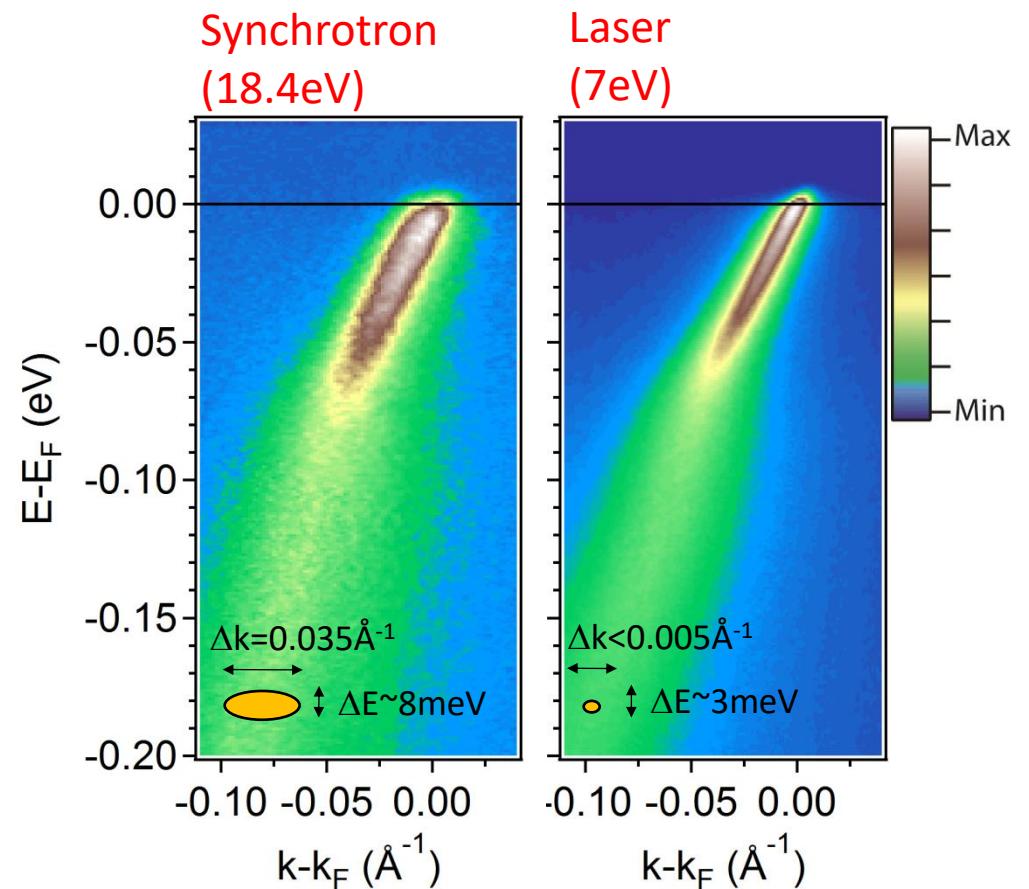
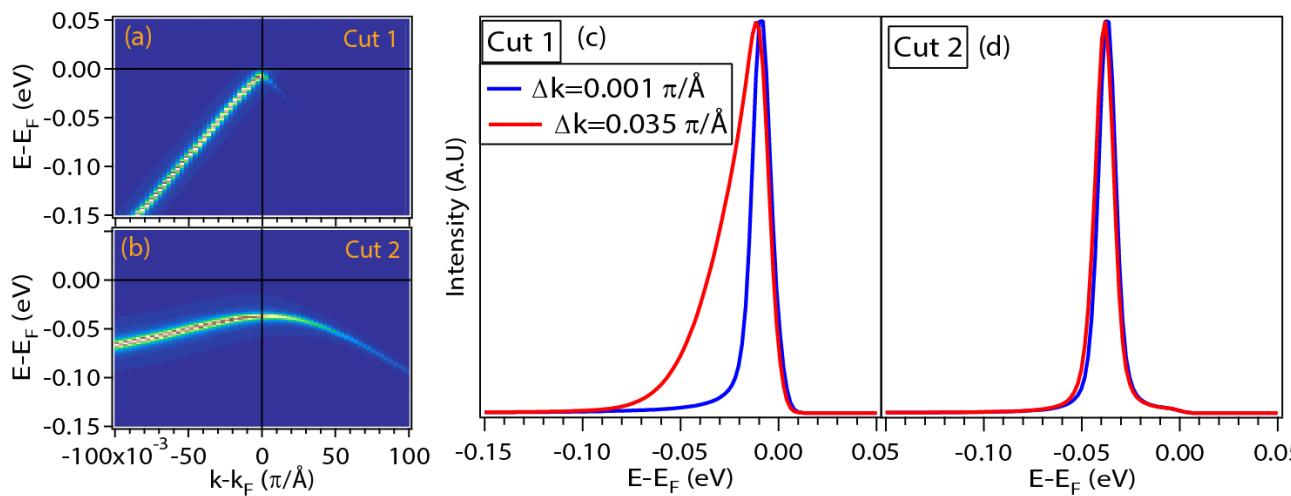
Example: highlighting ‘heavy’ bands

- Different parts of hybridized band structure originate from different orbitals
- Ce³⁺ corresponds to a 4f¹ electronic configuration.
- At 121 eV photon energy, there is resonance between a “core” 4d state and the 4f state.



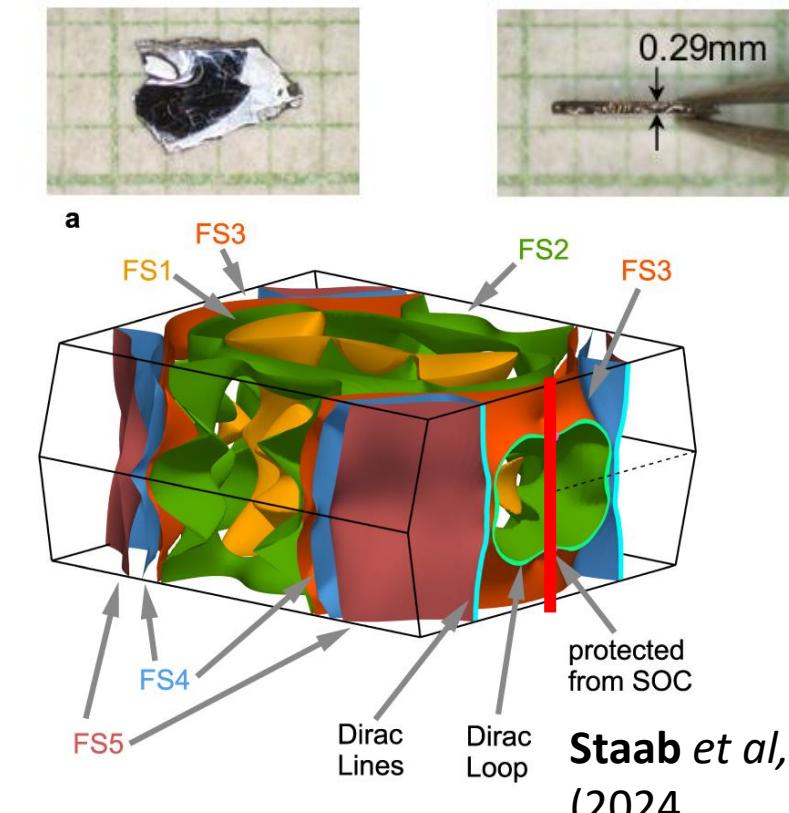
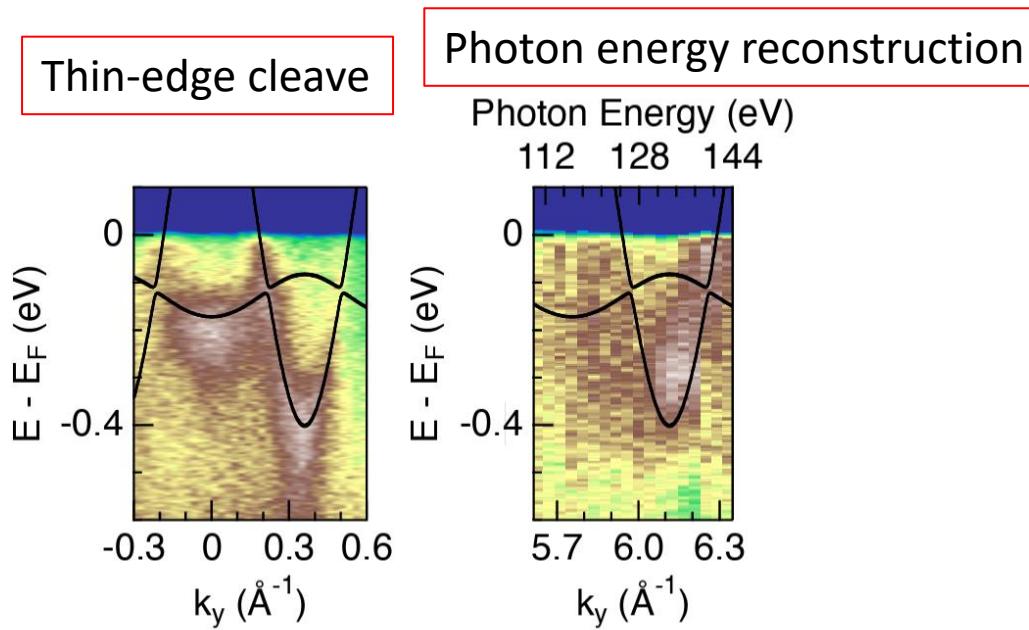
Resolution effects: energy and parallel momentum

- Instrument resolution: convolution of spectral function with resolution ellipsoid. It does not represent the smallest energy or momentum scale which can be resolved
- Tradeoffs to achieving better resolution which may be unacceptable for some experiments
- In strongly dispersing bands, momentum resolution can lead to energy broadening
- Most experiments are not operated at optimal/best resolution of instrument



Resolution effects: perpendicular momentum

- Photoelectrons are known to originate from a short depth inside the sample (e.g. $\lambda = 5\text{\AA}$)
- Short probing depth leads to quantum uncertainty in perpenidular momentum (e.g. $\Delta k_{\perp} = 0.2 \text{ \AA}^{-1}$)
- Δk_{\perp} can be large fraction of BZ
 - k_{\perp} dispersion becomes changed/muted
 - Precise determination of V_0 less critical for very surface sensitive experiments



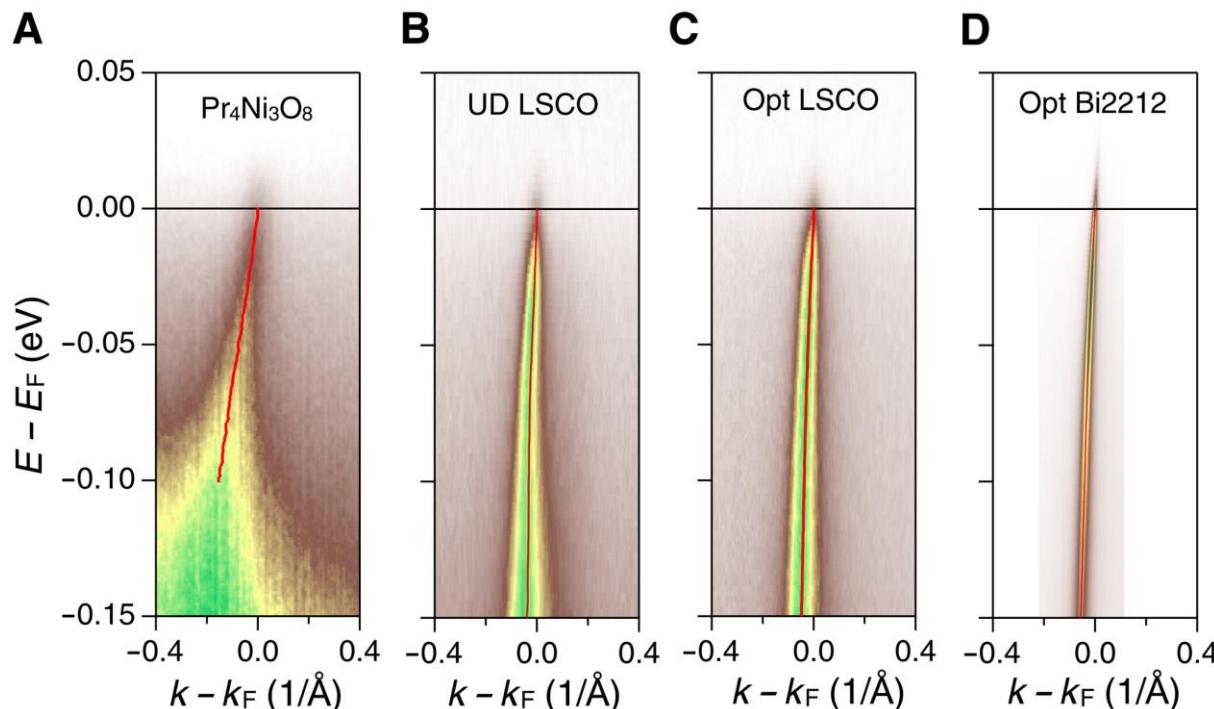
Resource for k_{\perp} broadening

V.N. Strocov Journal of Electron Spectroscopy and Related Phenomena 130 65–78 (2003)

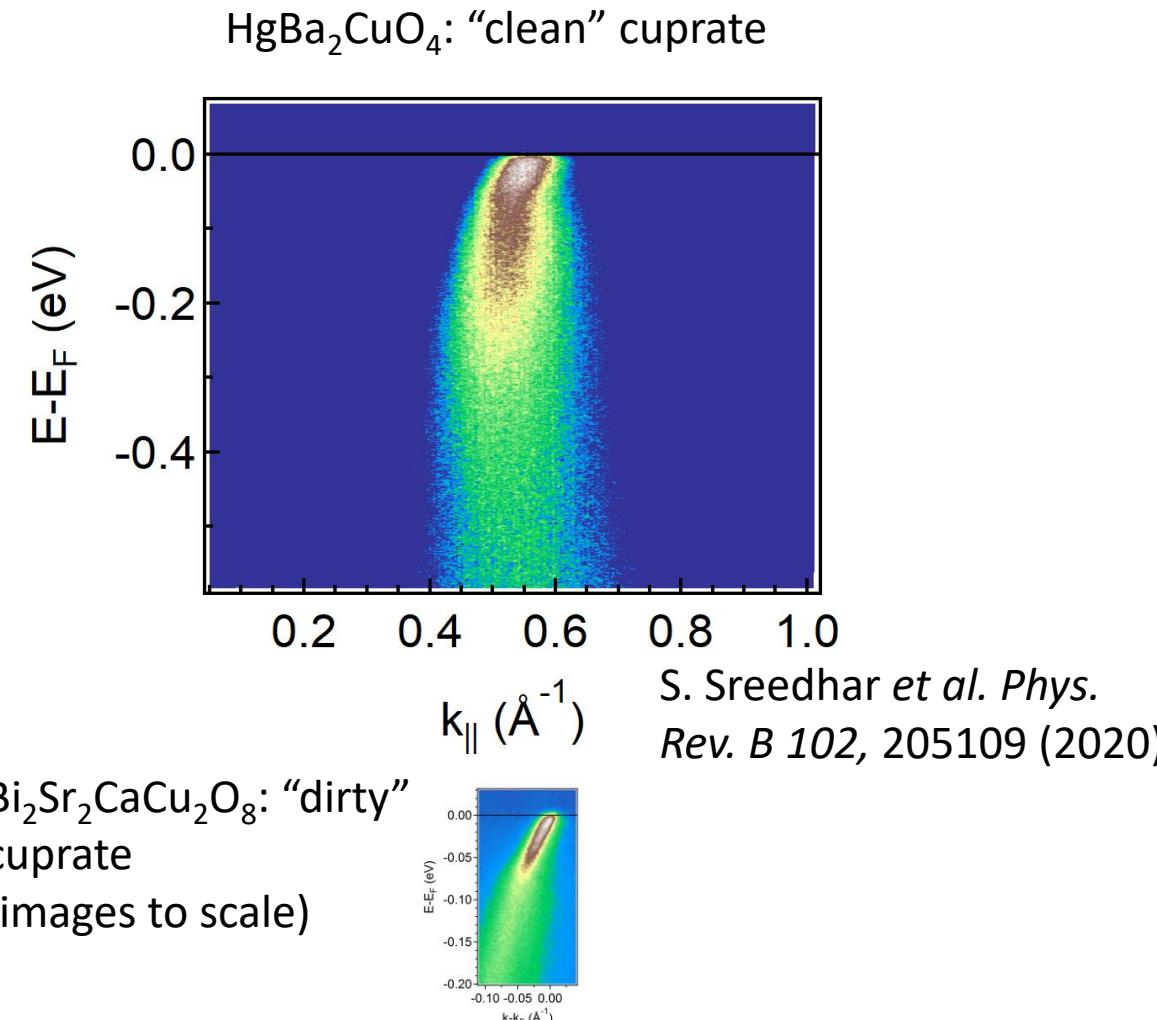
Resolution effects: other sources

- Sample inhomogeneity
 - Surface curvature or roughness
 - Chemical inhomogeneity
- Experimental un-idealities
 - Larger beam spot size
 - Electrical noise
 - Bandwidth of lightsource
 - Finite width of entrance slit
 - Space charging (electrons repelling each other after photoemission)

Sometimes the sample limits the precision of information ARPES can extract



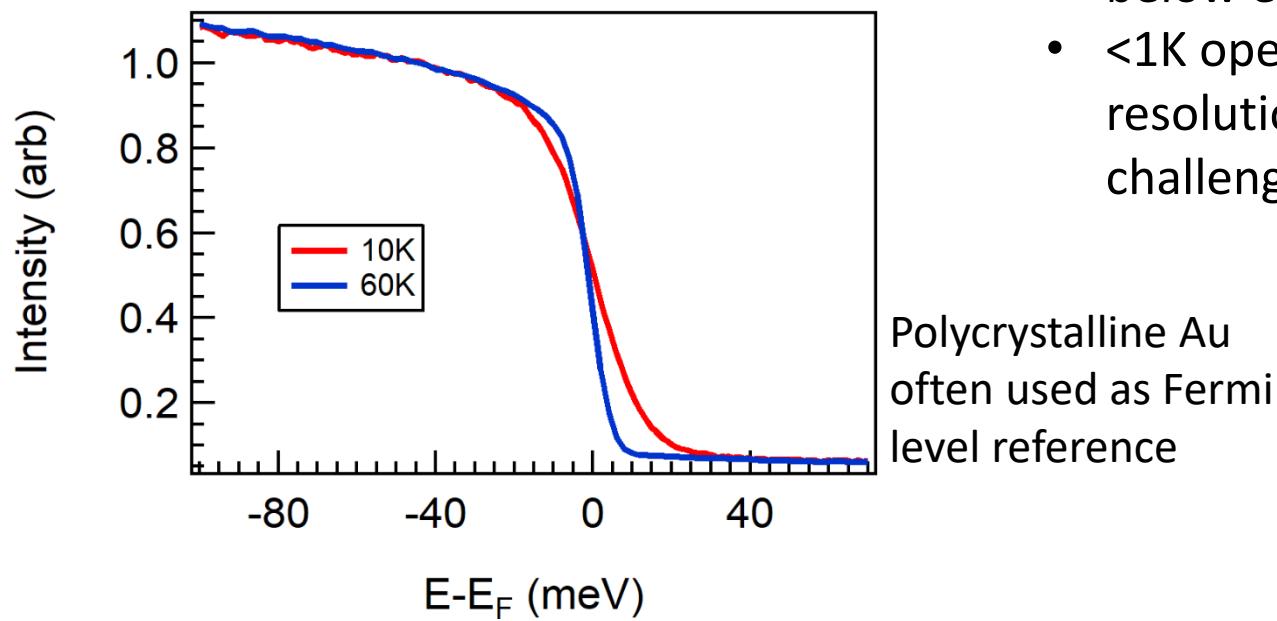
Haoxiang Li et al., Sci. Adv. 9, 4418 (2023)



Temperature

$$I(\mathbf{k}, \omega) = I_0(\mathbf{k}, \nu, \mathbf{A}) f(\omega) A(\mathbf{k}, \omega) \otimes R(\Delta k, \Delta \omega)$$

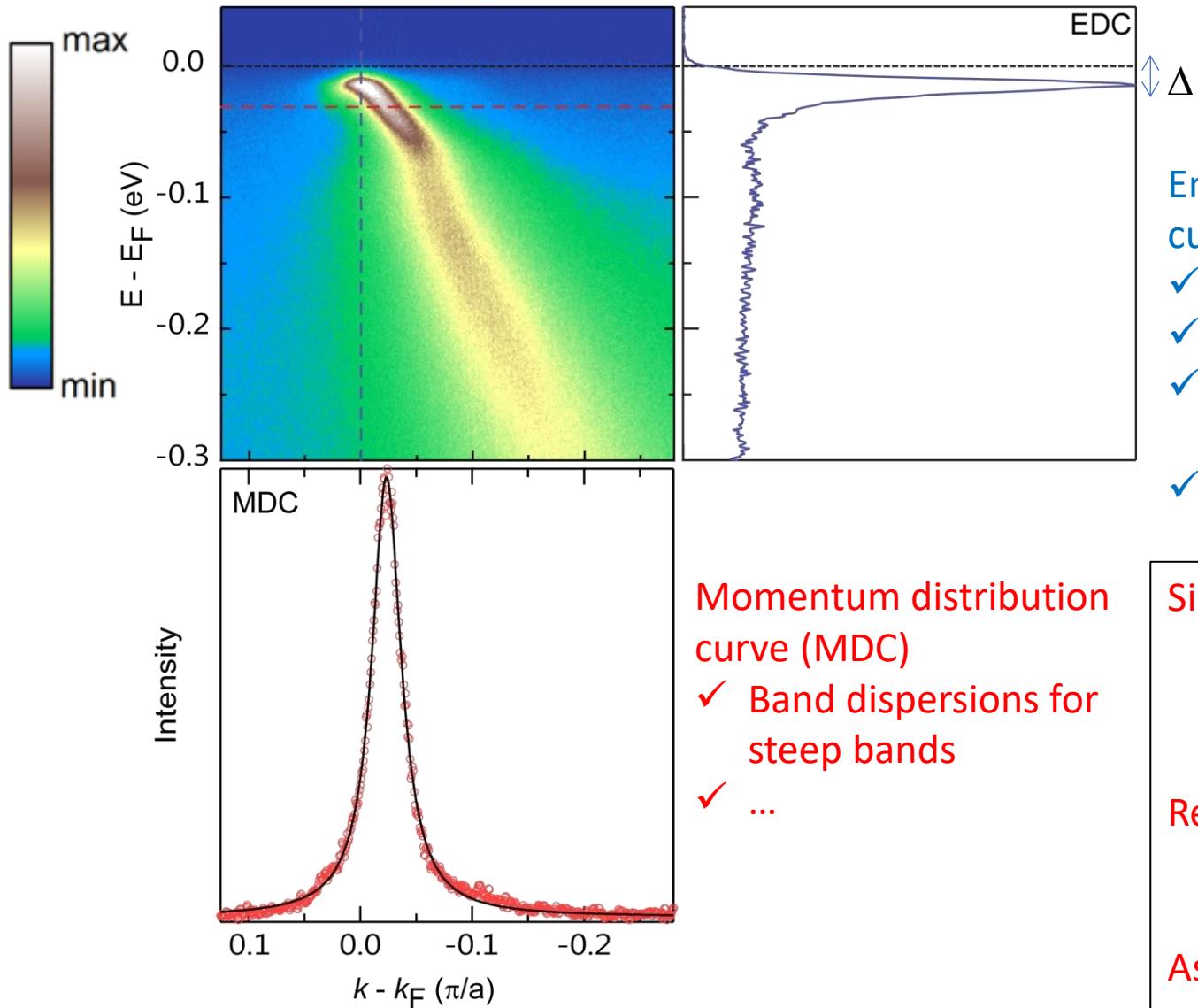
- Fermi-Dirac cutoff gets broader giving access to more unoccupied states
- Spectra get broader, generally following electron lifetime of material system



Temperature control during experiment:

- Flow cryostat
- Typical minimum temperature: 5-20K
- He-3 systems capable of reaching 1K or below exist but are rare
- <1K operation also requires energy resolution better than 1 meV, which is challenging

Slicing up ARPES data: terminology



Energy distribution curve (EDC)

- ✓ Spectral gaps
- ✓ Lineshapes
- ✓ Band dispersion for flatter bands
- ✓ ...

Momentum distribution curve (MDC)

- ✓ Band dispersions for steep bands
- ✓ ...

Single particle spectral function:

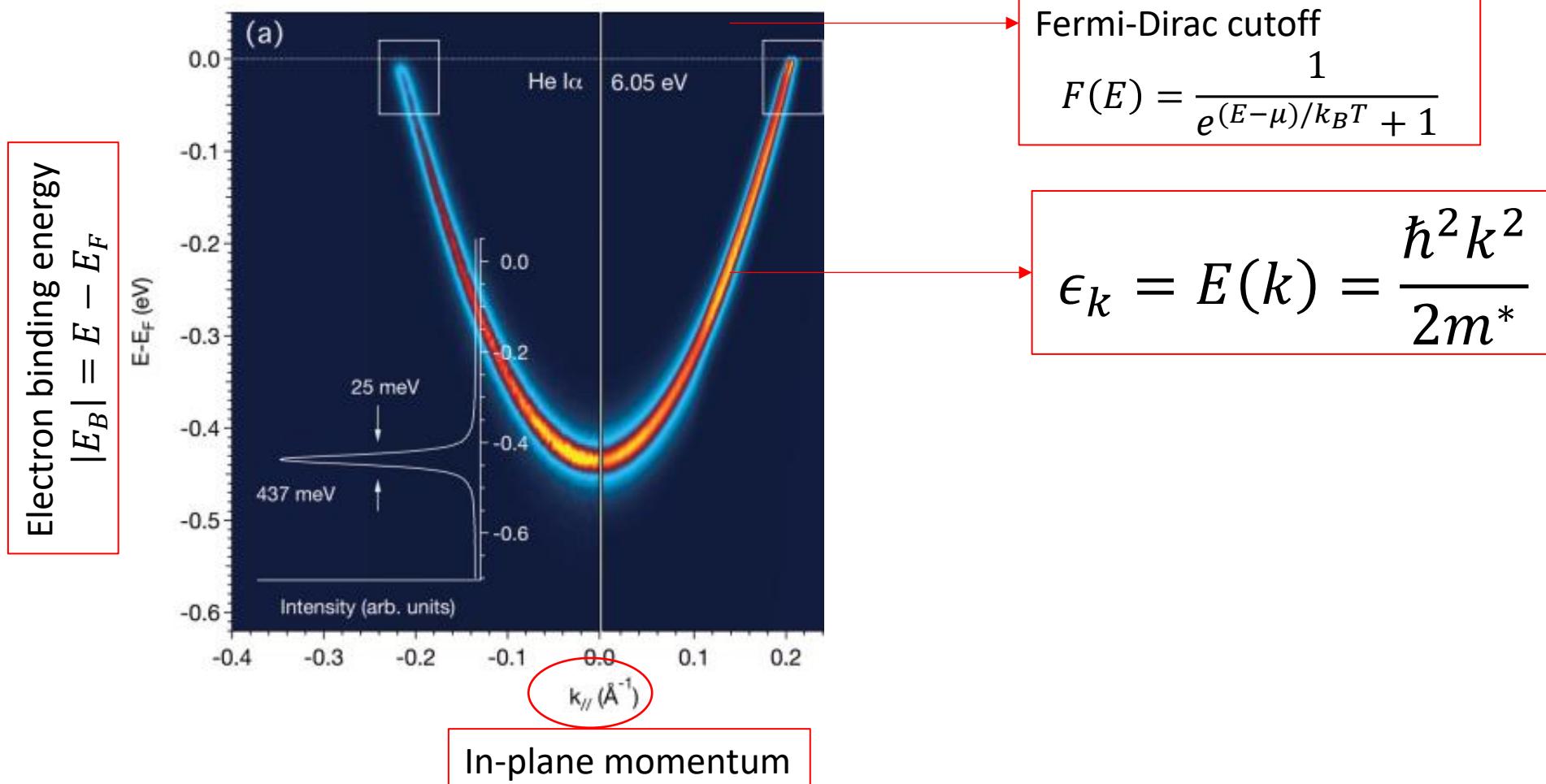
$$A(\mathbf{k}, \omega) = -\frac{1}{\pi} \frac{\Sigma''(\mathbf{k}, \omega)}{[\omega - \varepsilon_{\mathbf{k}} - \Sigma'(\mathbf{k}, \omega)]^2 + [\Sigma''(\mathbf{k}, \omega)]^2}$$

Real and imaginary part of self energy:

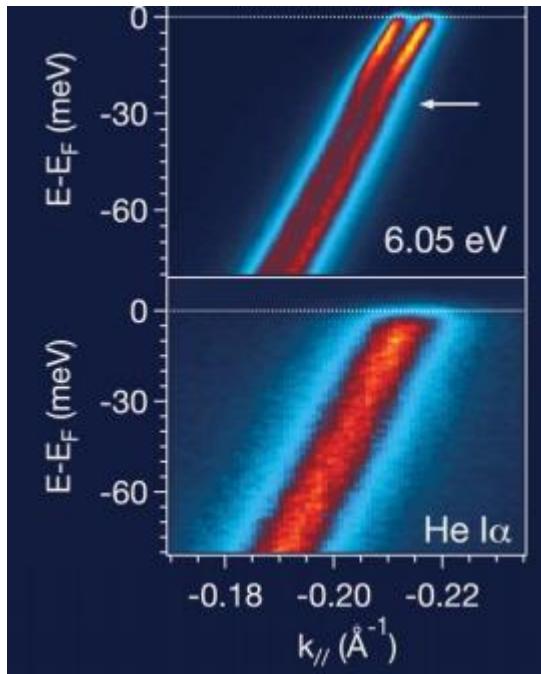
$$\Sigma(\mathbf{k}, \omega) = \Sigma'(\mathbf{k}, \omega) + i\Sigma''(\mathbf{k}, \omega)$$

Assume momentum-independent self energy within cut, so constant energy slices (MDC) are Lorentzian

Putting it all together: Cu (111) surface state



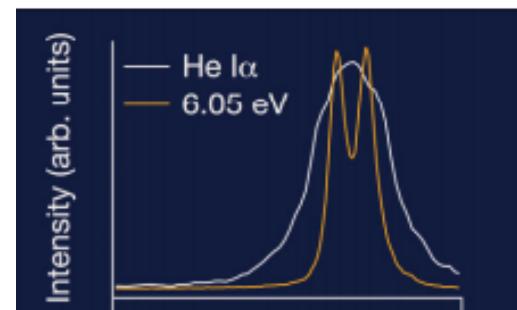
Interactions in simple system



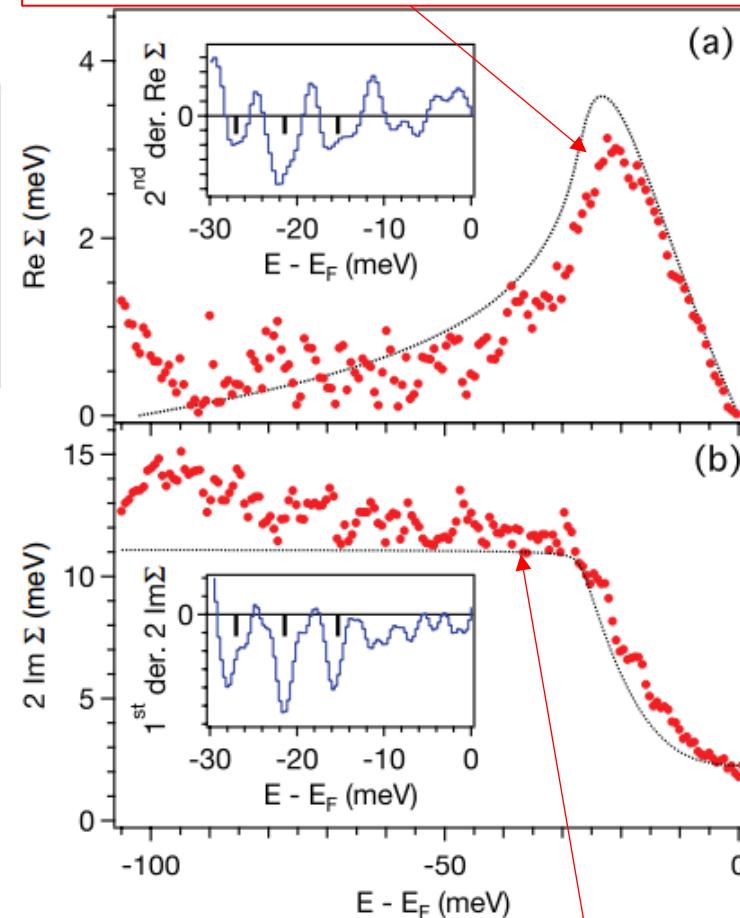
PRB **87**, 075113 (2013)

$$A(\mathbf{k}, \omega) = -\frac{1}{\pi} \frac{\sum''(\mathbf{k}, \omega)}{[\omega - \varepsilon_{\mathbf{k}} - \sum'(\mathbf{k}, \omega)]^2 + [\sum''(\mathbf{k}, \omega)]^2}$$

$$\sum(\mathbf{k}, \omega) \rightarrow \sum(\omega) = \sum'(\omega) + i \sum''(\omega)$$



Measured dispersion minus
calculated/assumed bare dispersion



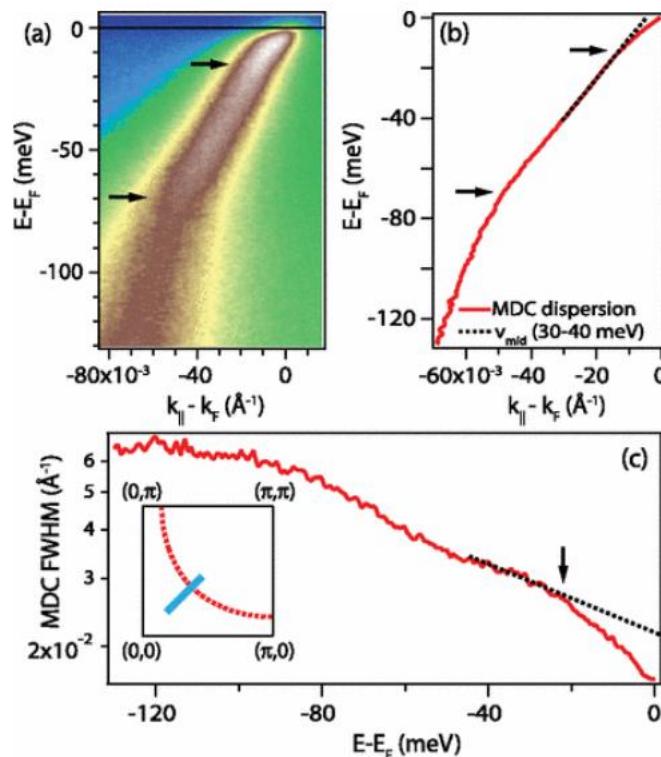
Electron
phonon-
coupling!

Width of peaks

Examples: interactions in more complex systems

Kinks in cuprates

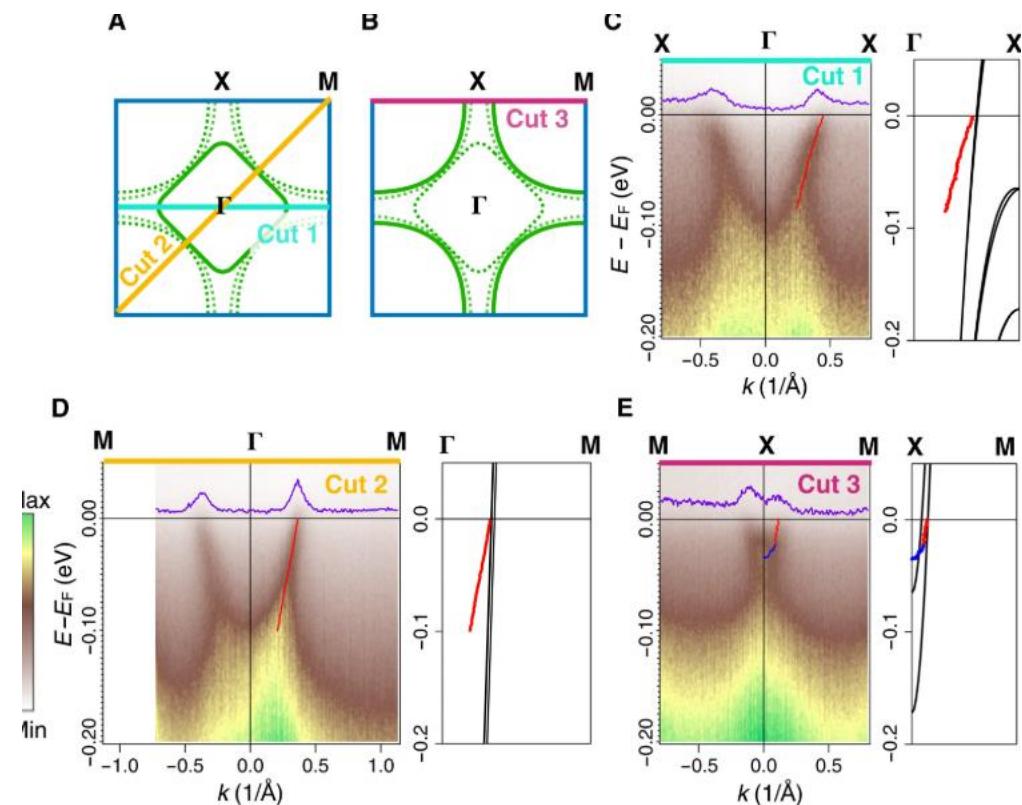
- Establishing origin requires input from other experiments
- Common energy scale in 2 channels attests to veracity of feature



Johnston, Vishik, et al, Phys. Rev. Lett. **108**, 166404 (2012)

Mass enhancement in planar nickelate

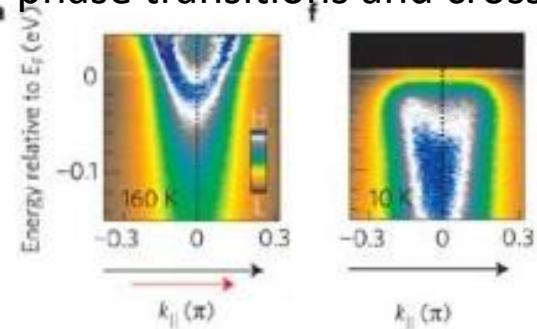
- Measured dispersion with smaller v_F or larger m^* is evidence of interactions
- Caution: dispersion can be established more precisely than linewidth



Haoxiang Li et al., Sci. Adv. **9**, 4418 (2023)

What can we accurately say about lineshapes and lifetime?

Sometimes big effects are seen at phase transitions and crossovers



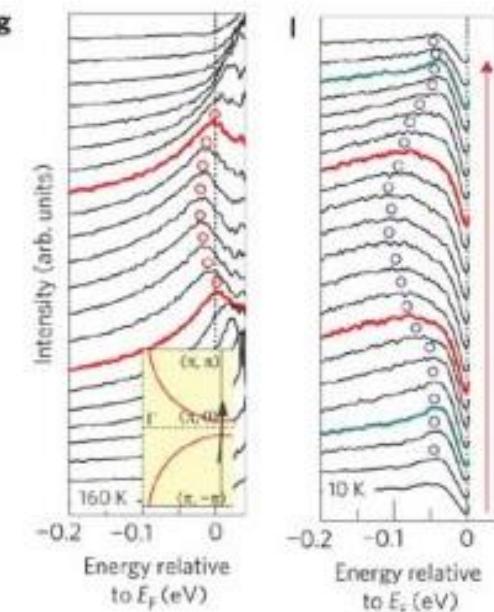
Assessing lifetimes from ARPES linewidths in 3D systems is complicated

$$\Gamma = \frac{\frac{\Gamma_i}{|v_{i\perp}|} + \frac{\Gamma_f}{|v_{f\perp}|}}{\left| \frac{1}{v_{i\perp}} \left[1 - \frac{mv_{i\parallel} \sin^2 \vartheta}{\hbar k_{\parallel}} \right] - \frac{1}{v_{f\perp}} \left[1 - \frac{mv_{f\parallel} \sin^2 \vartheta}{\hbar k_{\parallel}} \right] \right|}$$

2D non-interacting systems are safer

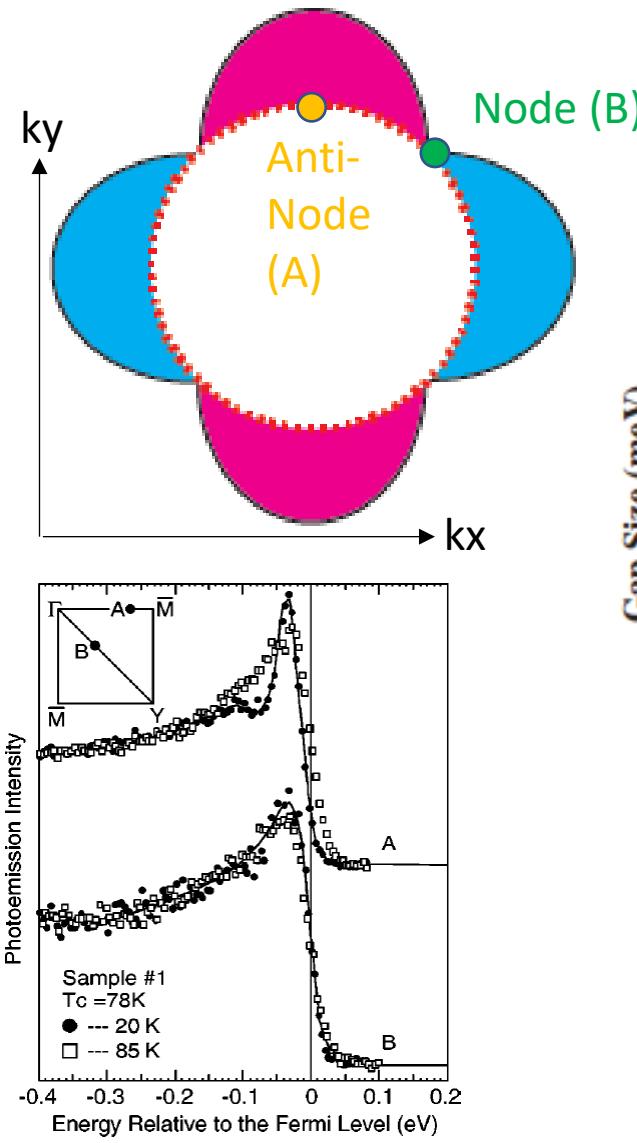
$$\Gamma = \frac{\Gamma_i}{\left| 1 - \frac{mv_{i\parallel} \sin^2 \vartheta}{\hbar k_{\parallel}} \right|} \equiv C \Gamma_i$$

Damascelli, Physica Scripta. Vol. T109, 61–74 (2004)

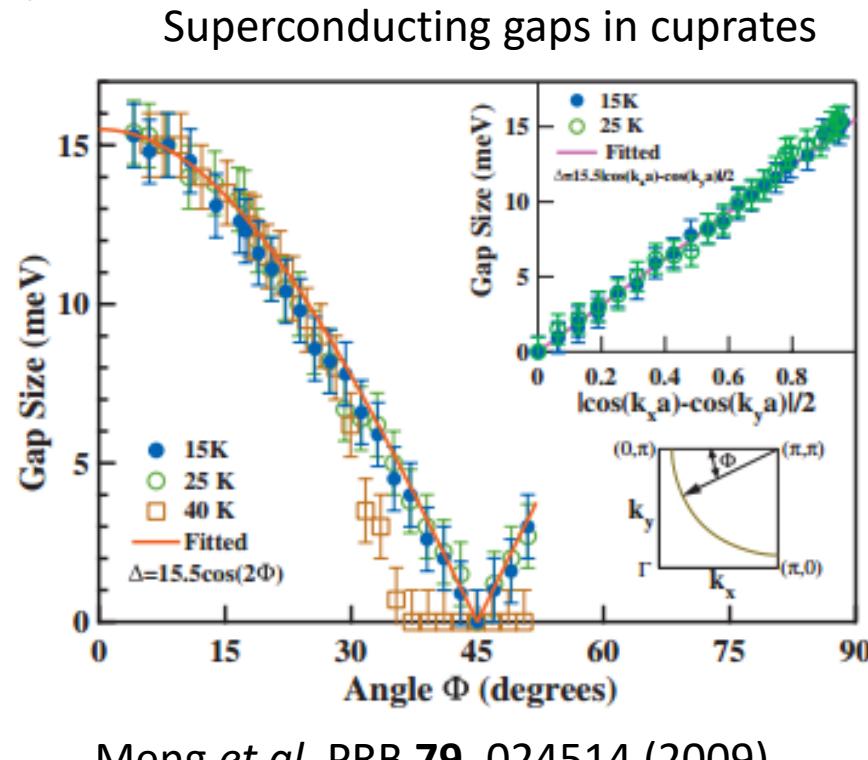


Caution: extrinsic effects usually contribute substantially to linewidth

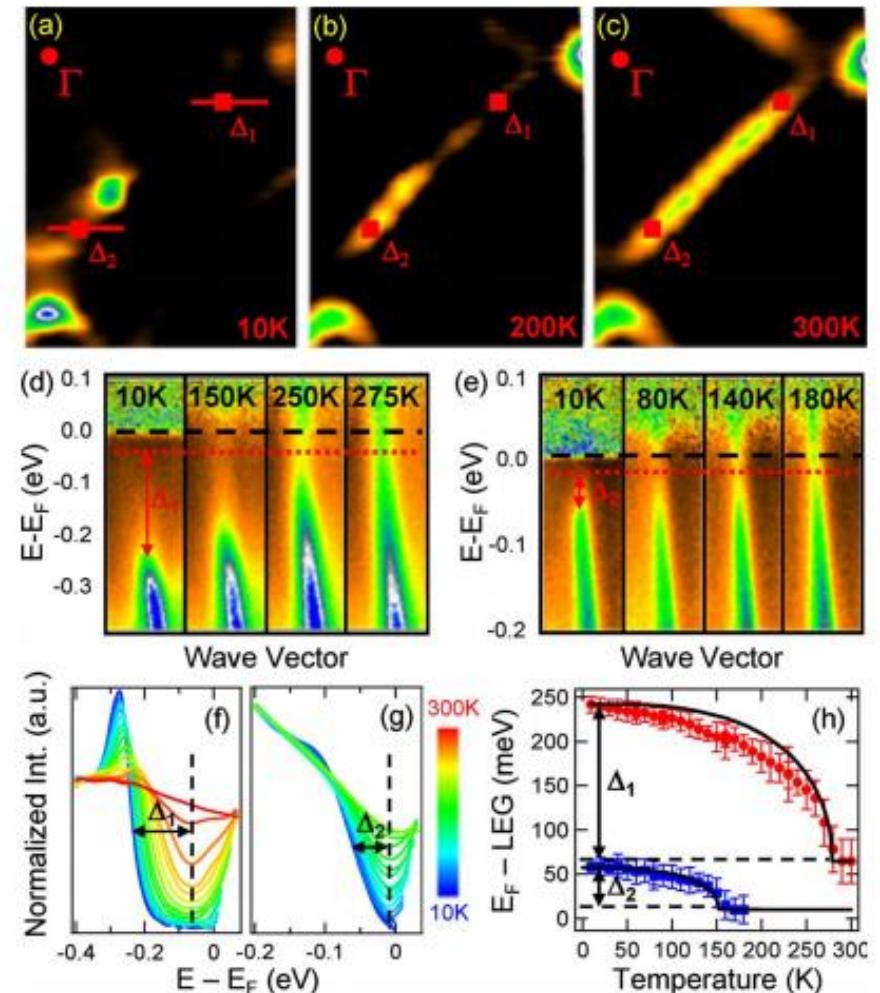
Quantifying spectral gaps with ARPES



Shen *et al.* PRL **70** (1993)



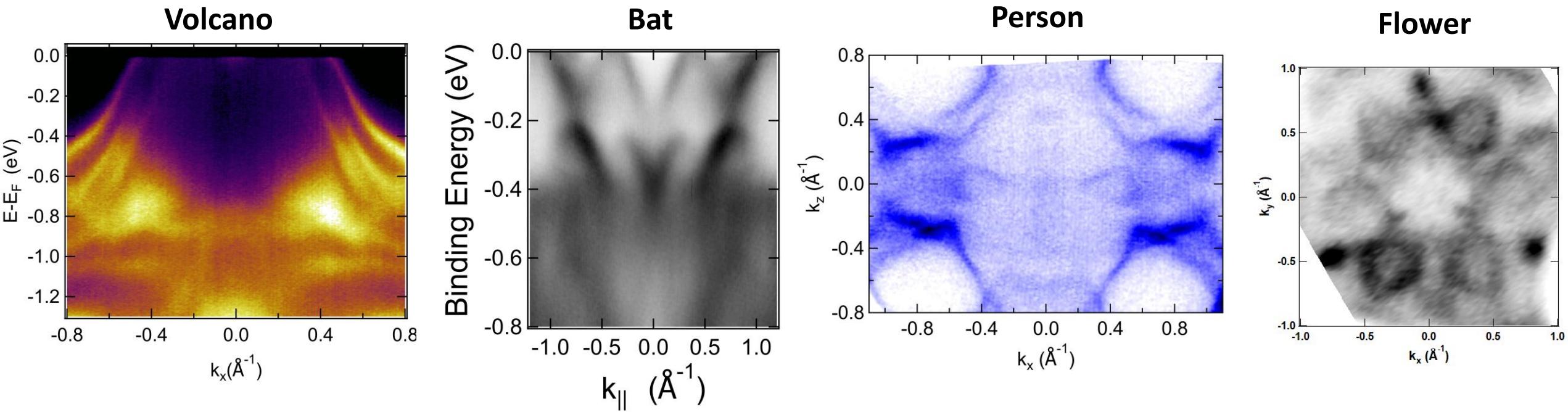
CDW gaps in ErTe_3



Twists on the ARPES technique

- Time-resolved ARPES
 - Pump-probe or two-photon photoemission
 - Tradeoff with resolution, limiting factor is lightsources
- Spin-resolved ARPES
 - Tradeoff with throughput and resolution
- Circular dichroism ARPES (poor man's spin-resolved)
 - Easier/faster experiment than spin-resolved, harder to interpret
- ARPES while perturbing sample (gate, current, small magnetic field)
 - Rare, challenging
- Micro and nanoARPES
 - No tradeoffs

ARPES is an information rich technique



Resources

- Campuzano, Norman, Randeria. *Photoemission in the high-T_c superconductors.* <https://arxiv.org/pdf/cond-mat/0209476.pdf>
- Damascelli, Hussain, Shen. *Angle-resolved photoemission studies of the cuprate superconductors.* Rev. Mod. Phys. **75** 473 (2003)
- Damascelli. *Probing the Electronic Structure of Complex Systems by ARPES.* Physica Scripta. Vol. T109, 61–74, 2004
- Moser, ‘An experimentalist’s guide to the matrix element in angle resolved photoemission’ Journal of Electron Spectroscopy and Related Phenomena **214** 29–52 (2017)
- Sobota, He, Shen. *Angle-resolved photoemission studies of quantum materials.* Rev. Mod. Phys. **93**, 025006 (2021)
- V.N. Strocov Journal of Electron Spectroscopy and Related Phenomena 130 65–78 (2003)
- E. Rotenberg and A. Bostwick, “microarpes and nanoarpes at diffraction-limited light sources: opportunities and performance gains,” Journal of Synchrotron Radiation, vol. 21, no. 5, pp. 1048–1056 (2014)

Extra slides

ARPES (CW) light sources: compare/contrast

Type	Available photon energies	Bandwidth/mo nochromaticity	Intensity	Polarization	Versatility
Laser	6-11 eV; not much variation for a given laser; for time-resolved experiments: HHG sources (meh)	Can be <<1 meV	Potentially high	Usually Variable polarization	Low; does not work on every material; usual fixed photon energy gives incomplete info about 3D materials
Gas (He, Xe, Ne, Ar...) discharge lamp	21.2, 40.8, 8.4, 9.6, 11.6 eV (and more)	Can be small (<1 meV) with monochromator	Moderate	unpolarized	Low-moderate; fixed photon energy gives incomplete info about 3D materials
Synchrotron	Variable; different synchrotrons and endstations specialize in different energy ranges	Can be <1meV; tradeoff between bandwidth/intensity	Often high, sometimes tradeoffs with bandwidth	Usually variable	High; tunable photon energy allows to optimize matrix elements and study 3D materials

$$E_{kin} = h\nu - \phi - |E_B|$$

$$\mathbf{p}_{\parallel} = \hbar\mathbf{k}_{\parallel} = \sqrt{2mE_{kin}} \cdot \sin \vartheta$$

$$M_{f,i}^k \equiv \langle \phi_f^k | -\frac{e}{mc} \mathbf{A} \cdot \mathbf{p} | \phi_i^k \rangle$$

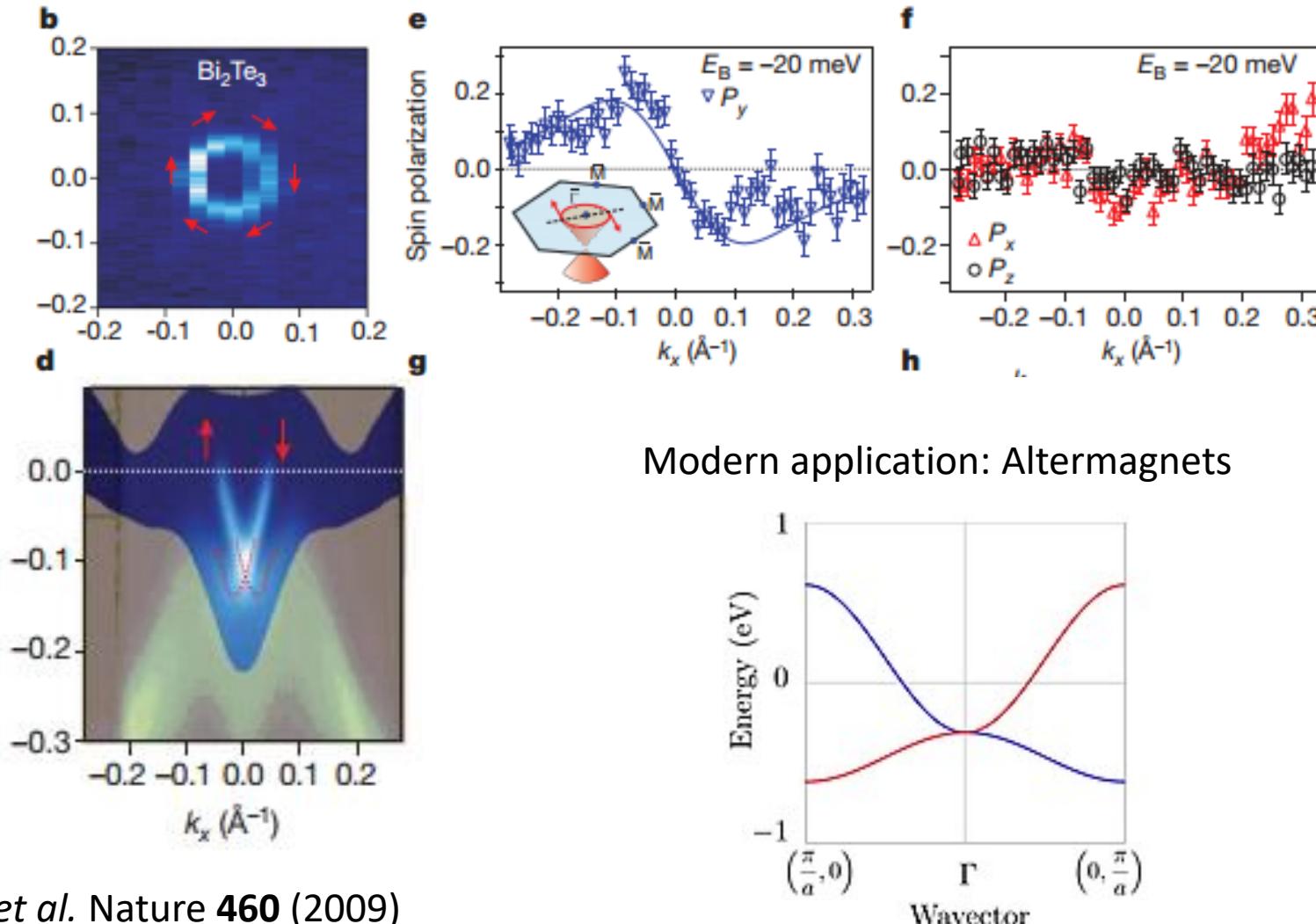
Spin resolved ARPES

How can we measure electron spin in photoemission experiments?

Method	Interaction	Operation voltage	S_{eff}	Figure of merit	Target
Mott	Spin-orbit	20–100 kV	0.1–0.2	$1\text{--}5 \times 10^{-4}$	Au thin film
SPLEED	Spin-orbit	150 V	0.2–0.3	$1\text{--}2 \times 10^{-4}$	W single crystal
Diffuse scattering	Spin-orbit	150 V	~0.2	$\sim 1 \times 10^{-4}$	Au thin film
VLEED	Spin-exchange	6–10 V	0.3–0.4	$\sim 10^{-2}$	Fe single crystal

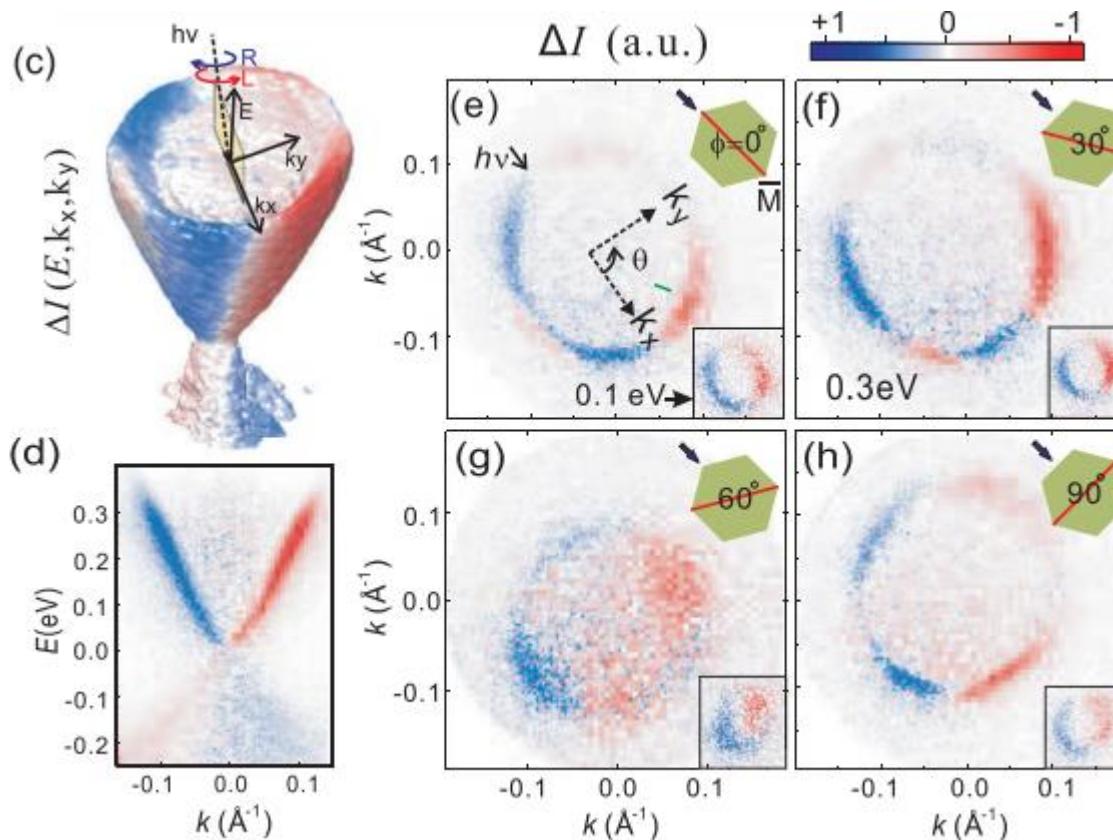
A. Takayama, *High-resolution spin-resolved photoemission spectrometer and the Rashba effect in Bismuth thin films* (2015)

Spin-momentum locking in topological insulators



Spin texture via circular dichroism

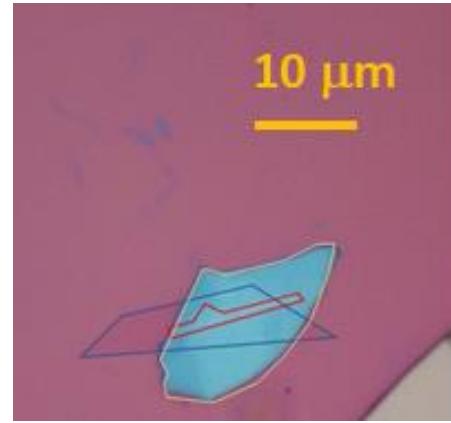
1. Measure ARPES spectrum with left-circularly polarized (LCP) light
2. Measure ARPES spectrum with right-circularly polarized (RCP) light
3. $\Delta I(E, k_x, k_y) = I_{LCP} - I_{RCP}$



- Benefits:
 - Possible with most lightsources
 - High throughput/resolution
- Challenges:
 - Spin+orbital
 - Final state effects

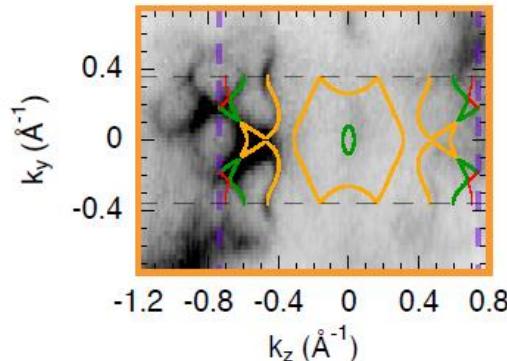
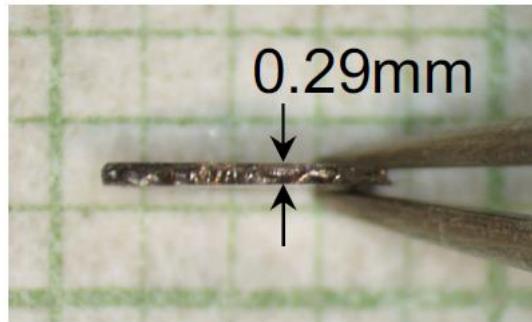
Wang *et al.* PRL **107**,
207602 (2011)

micro/nanoARPES have enabled more materials to be ARPESed

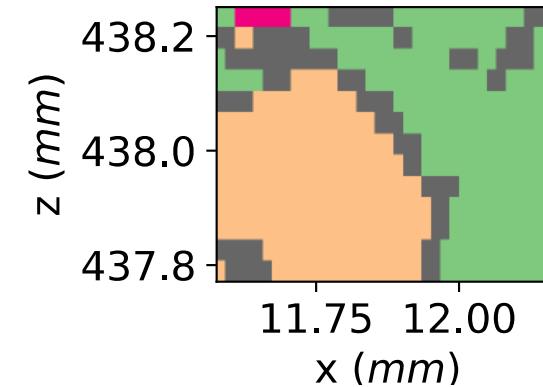


Exfoliated materials and heterostructures

Samples with small or irregular cleaves



Staab *et al*, Physical Review B 110 (16), 165115 (2024)



Samples with mesoscale chemical or electronic inhomogeneity

A. Rossi *et al*, Phys. Rev. B 104, 155115 (2021)

S. Sreedhar *et al*, *in preparation*

Relationship between ARPES and single particle spectral function

- Photoemission removes an electron and inverse photoemission adds an electron
- Electron removal/addition described by one-electron addition and removal Green's function:

$$G^\pm(\mathbf{k}, \omega) = \sum_m \frac{|\langle \Psi_m^{N\pm 1} | c_{\mathbf{k}}^\pm | \Psi_i^N \rangle|^2}{\omega - E_m^{N\pm 1} + E_i^N \pm i\eta}$$

$c_{\mathbf{k}}^\pm$ creates/annihilates electron with energy ω and momentum \mathbf{k}
 η is positive infinitesimal

- Retarded Green's function is related to one-electron spectral function via:

$$G(\mathbf{k}, \omega) = \int_{-\infty}^{\infty} d\omega' \frac{A(\mathbf{k}, \omega')}{\omega - \omega' \pm i\eta}$$

- $(x \pm i\eta)^{-1} = \mathcal{P} \left(\frac{1}{x} \right) \mp i\pi\delta(x), \eta \rightarrow 0^+$
- $-\left(\frac{1}{\pi} \right) \text{Im } G(\mathbf{k}, \omega) = A^+(\mathbf{k}, \omega) + A^-(\mathbf{k}, \omega)$ where $G(\mathbf{k}, \omega)$ is the retarded Green's function given by $G(\mathbf{k}, \omega) = G^+(\mathbf{k}, \omega) + [G^-(\mathbf{k}, \omega)]^*$

Single particle spectral function (continued)

- $A^\pm(\mathbf{k}, \omega) = \sum_m |\langle \Psi_m^{N\pm 1} | c_\mathbf{k}^\pm | \Psi_i^N \rangle|^2 \delta(\omega - E_m^{N\pm 1} + E_i^N)$
- Corrections to Green's function originating from interactions:

$$G(\mathbf{k}, \omega) = \frac{1}{\omega - \epsilon_{\mathbf{k}} - \Sigma(\mathbf{k}, \omega)}$$

where $\epsilon_{\mathbf{k}}$ is bare band dispersion, and $\Sigma(\mathbf{k}, \omega) = \Sigma'(\mathbf{k}, \omega) + i \Sigma''(\mathbf{k}, \omega)$ is the self-energy

- This allows to write the single-particle spectral function in terms of self energies as well:

$$A(\mathbf{k}, \omega) = -\frac{1}{\pi} \frac{\Sigma''(\mathbf{k}, \omega)}{[\omega - \epsilon_{\mathbf{k}} - \Sigma'(\mathbf{k}, \omega)]^2 + [\Sigma''(\mathbf{k}, \omega)]^2}$$

Pump-probe experiments

The pump

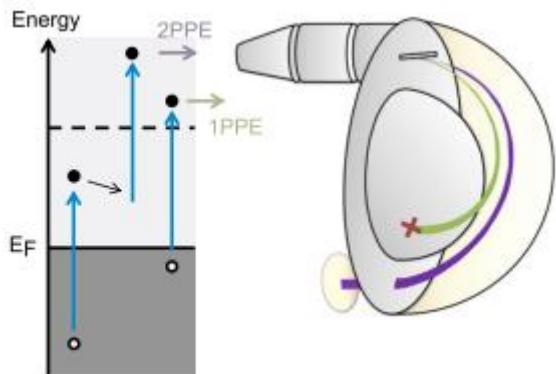
- Purpose (depends on specific experiment)
 - Create specific excitation
 - Whack the electronic system on a timescale faster than lattice response
 - Cause destruction
- Frequency (depends on specific experiment)
 - 1.5 eV (straight out of the Ti-Sapph laser)
 - Mid-IR (70-500 meV—relevant to excitations in solids)

The probe

- Ascertains system's response as a function of time delay from pump
- Defines what experiment you are doing
 - Optics (probe measures change in reflectivity or absorption)
 - THz (measures changes in optical conductivity at low frequencies)
 - ARPES (measures changes in band structure)
 - Many others

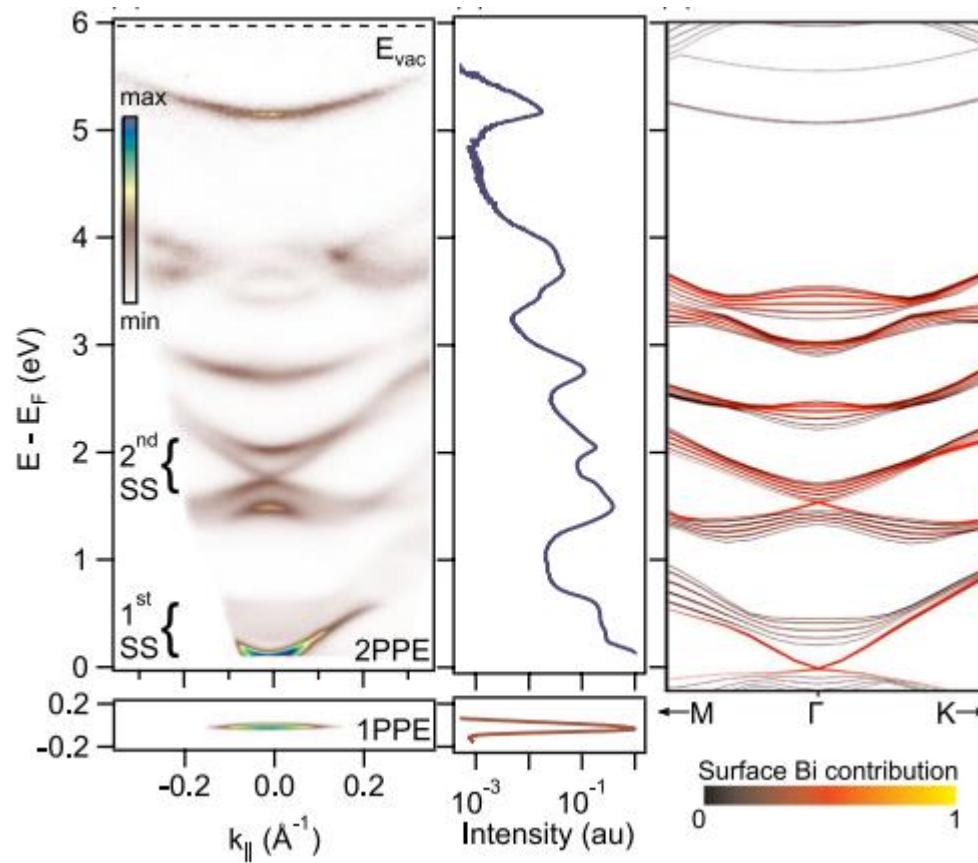
2 photon photoemission (2PPE) as a substitute for inverse photoemission

Photoemission	Photon in, electron out	Measure occupied electronic states	Sub-meV resolution common
Inverse photoemission	Electron in, photon out	Measure unoccupied electronic states	~500 meV resolution



- Use time-resolved ARPES to measure unoccupied states
- Pulse 1 (pump): make excitation into unoccupied state
 - Pulse 2 (probe): perform photoemission out of pump-populated unoccupied state
 - Time resolution is not very important, but light **intensity** is because this is 2nd order process

2 PPE experiments in Bi_2Se_3

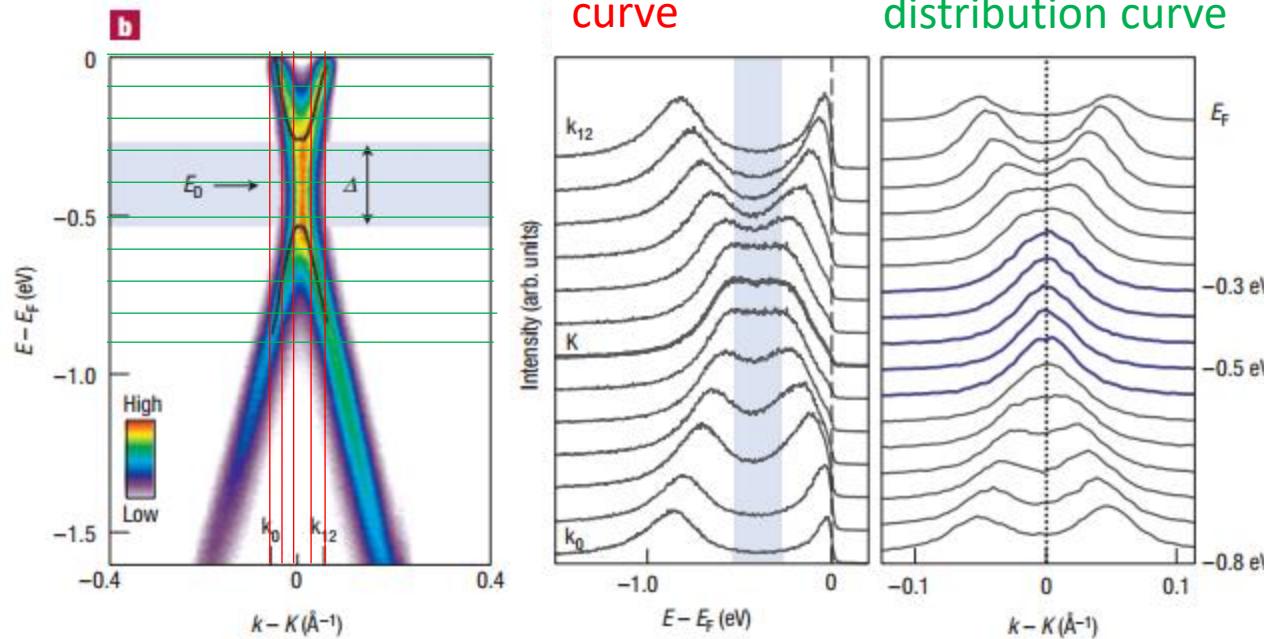


- 1.5 eV pump, 5.98 eV probe, $\Delta t \sim 100 fs$
- 2nd surface state observed above E_F !
- Applicable to many different materials

Looking at data...

EDC: Energy distribution curve

MDC: Momentum distribution curve



Zhou *et al* Nat. Mater 6 770 (2007)

Main result: substrate (SiC) breaks sublattice symmetry of graphene, opening a gap at the Dirac point

Which analysis (EDC or MDC) illustrates this result better?